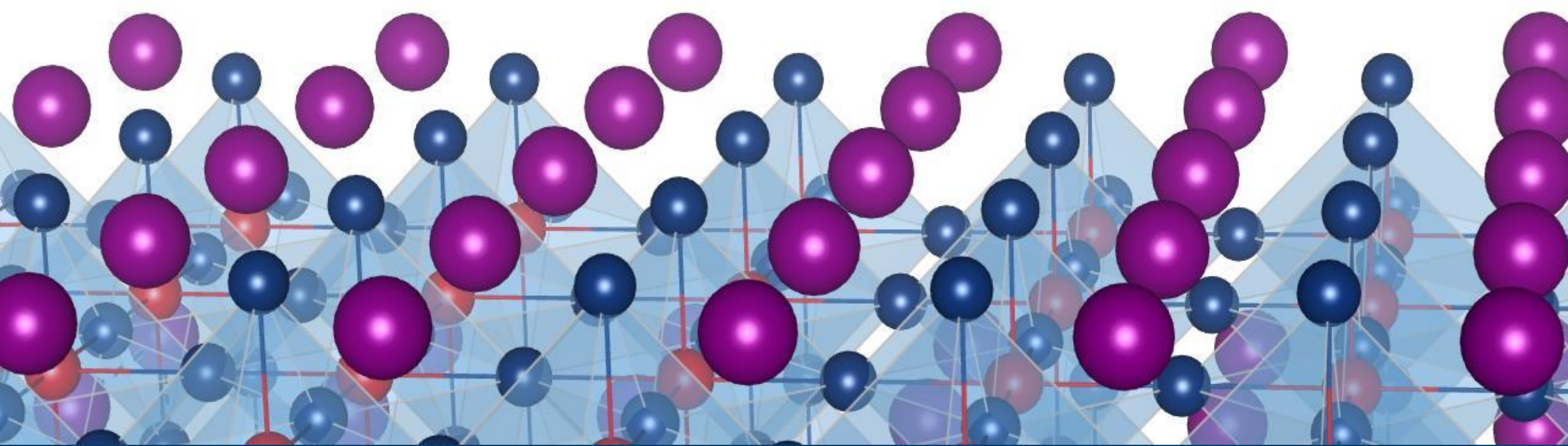


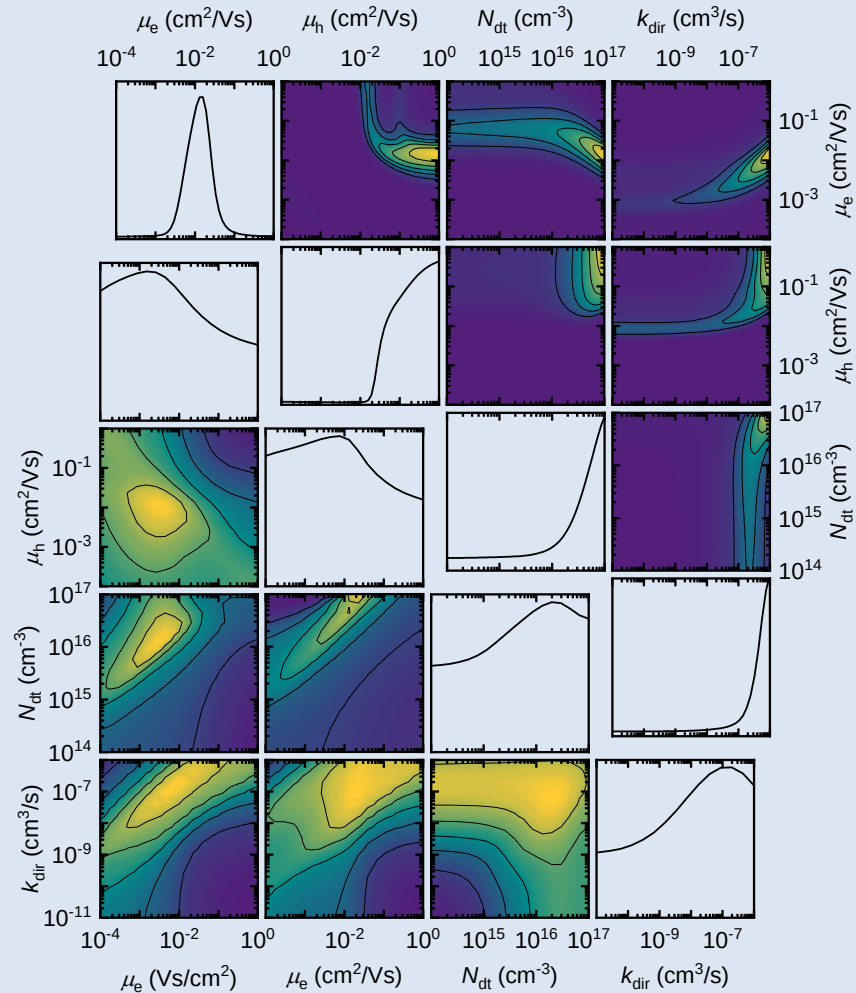


TRANSFORMING CHARACTERIZATION DATA INTO INFORMATION IN EMERGING SOLAR CELLS

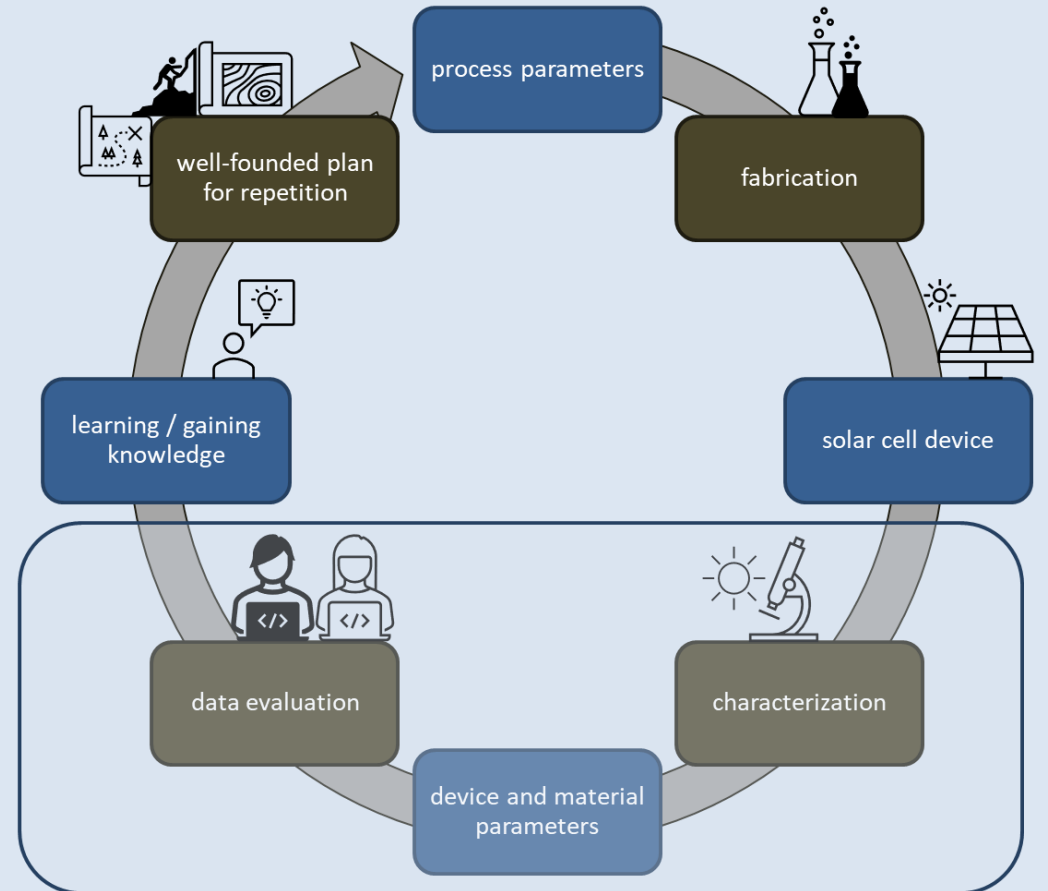
Thomas Kirchartz, Paula Hartnagel, Leonard Christen

IEK-5 Photovoltaik, Forschungszentrum Jülich

1) Inferring Parameters

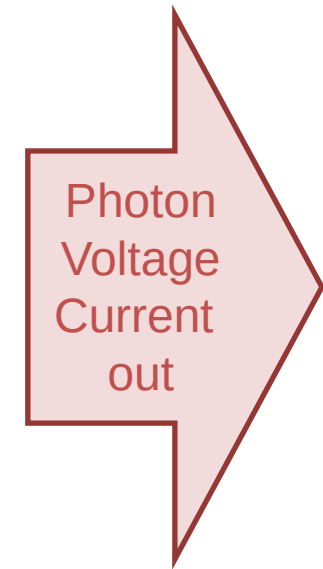
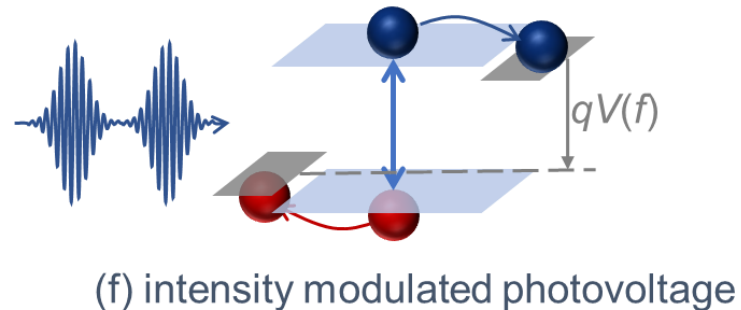
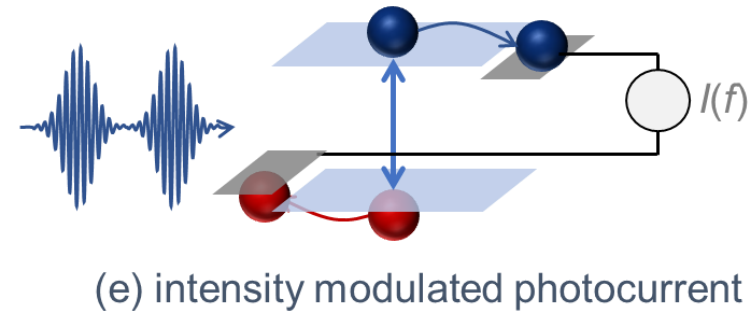
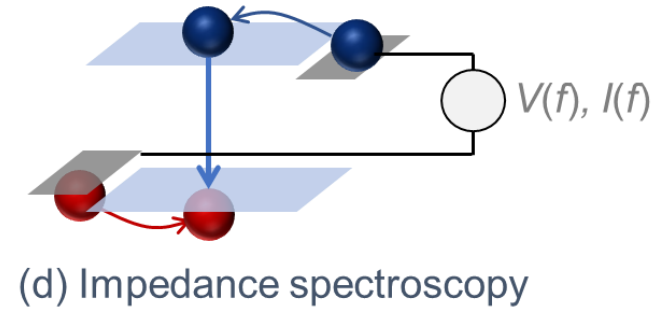
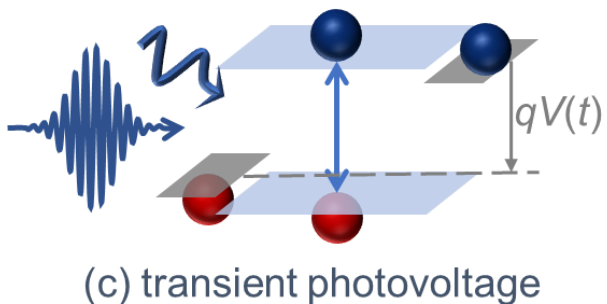
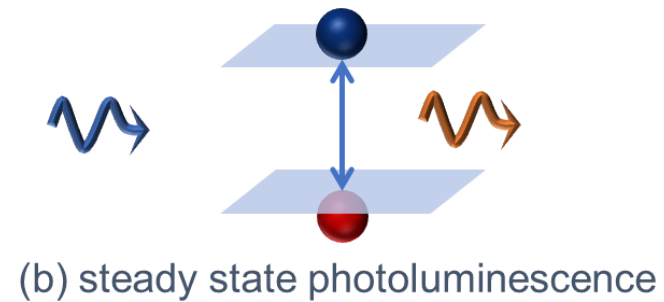
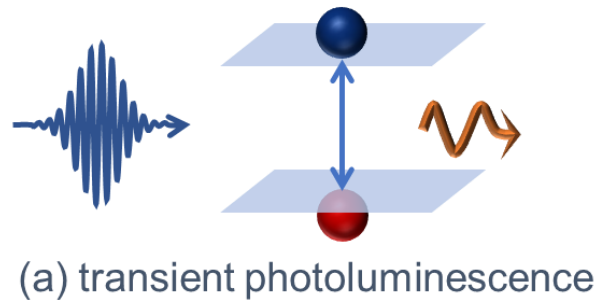
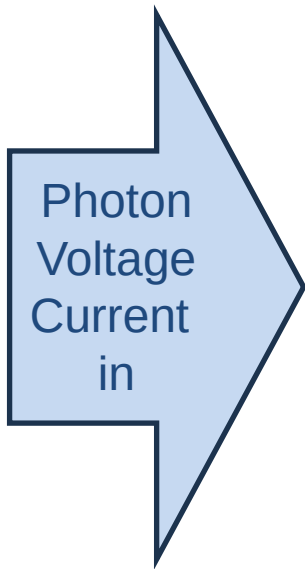


2) Value of Device Characterization



The Challenge

Interpreting methods to infer electronic properties



The Challenge

Interpreting methods to infer electronic properties

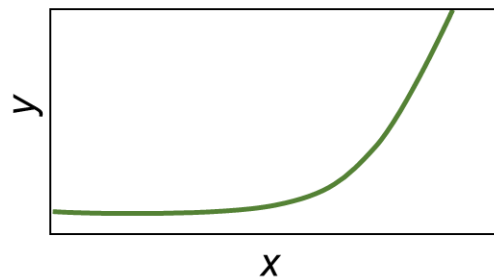
(a) Forward Problem

Material parameters, e.g. μ , τ , α , S ...

$$\begin{aligned}\frac{dn}{dt} &= G - R + D_n \frac{d^2 n}{dx^2} + \mu_n F \frac{dn}{dx} \\ \frac{dp}{dt} &= G - R + D_p \frac{d^2 p}{dx^2} - \mu_p F \frac{dp}{dx} \\ \frac{d^2 \phi}{dx^2} &= -\frac{\rho}{\epsilon}\end{aligned}$$

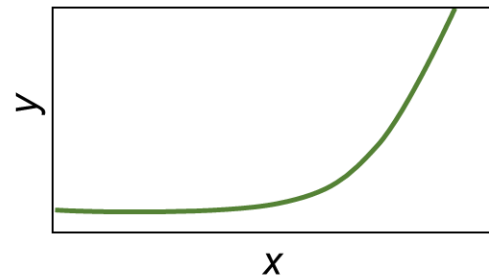
& appropriate boundary conditions

Simulated experimental data



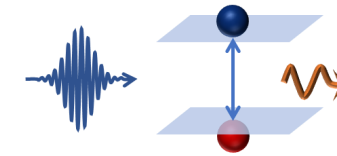
(b) Inverse Problem

Measured experimental data

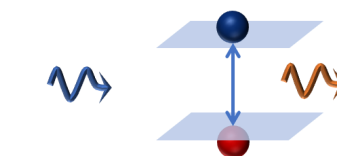


Algorithm searching for suitable material parameters to explain the experimental data using simulations.

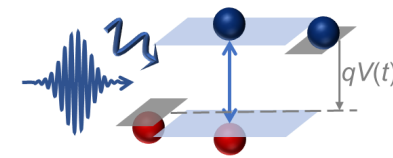
Material parameters, e.g. μ , τ , α , S ...



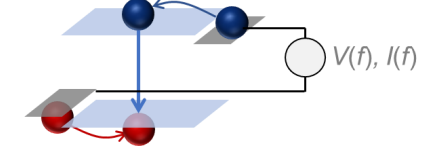
(a) transient photoluminescence



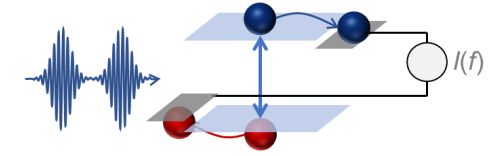
(b) steady state photoluminescence



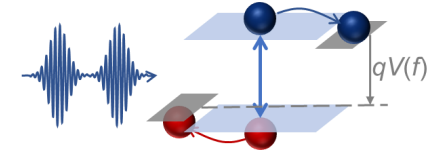
(c) transient photovoltage



(d) Impedance spectroscopy



(e) intensity modulated photocurrent



(f) intensity modulated photovoltage

What could possibly go wrong?

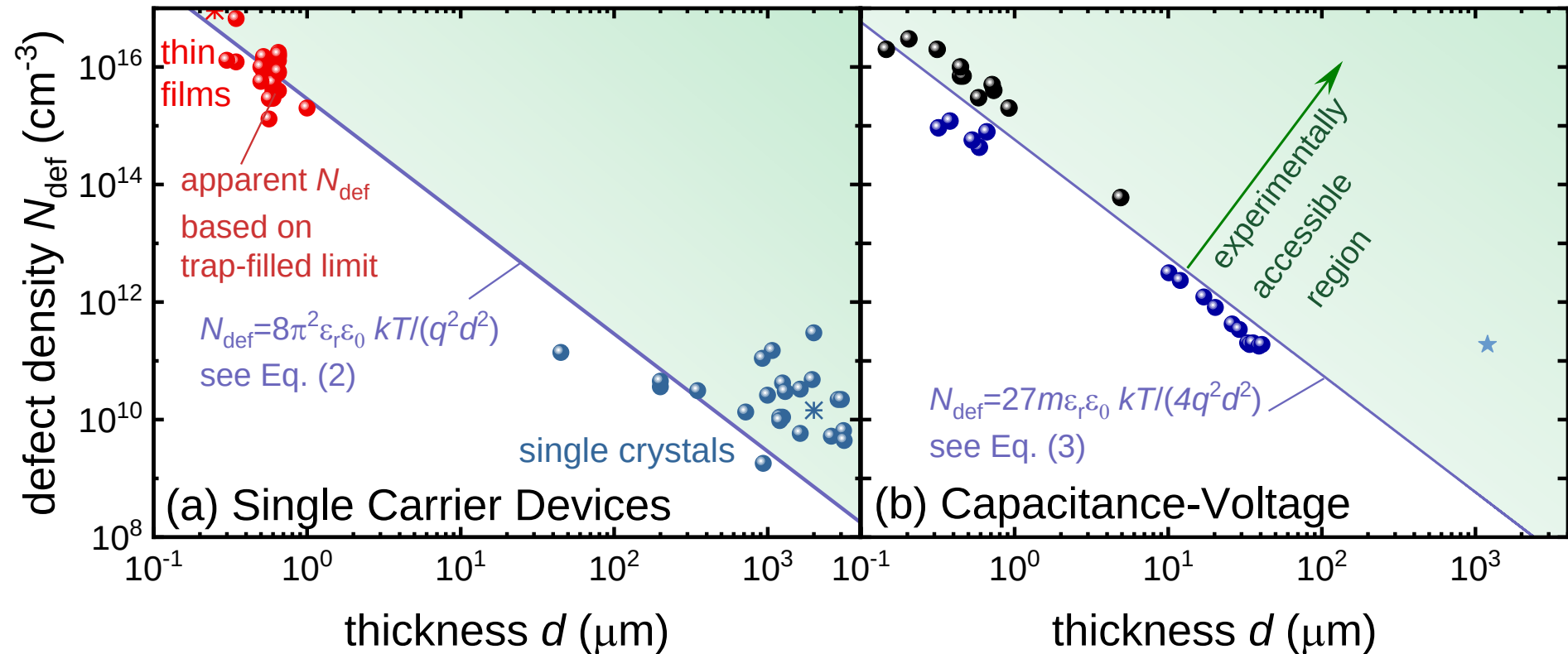
Trap densities

Observation:

Trap density scale with ϵ/d^2

Problem:

Detection limits given by Poisson equation cause the ϵ/d^2 trend.



What could possibly go wrong?

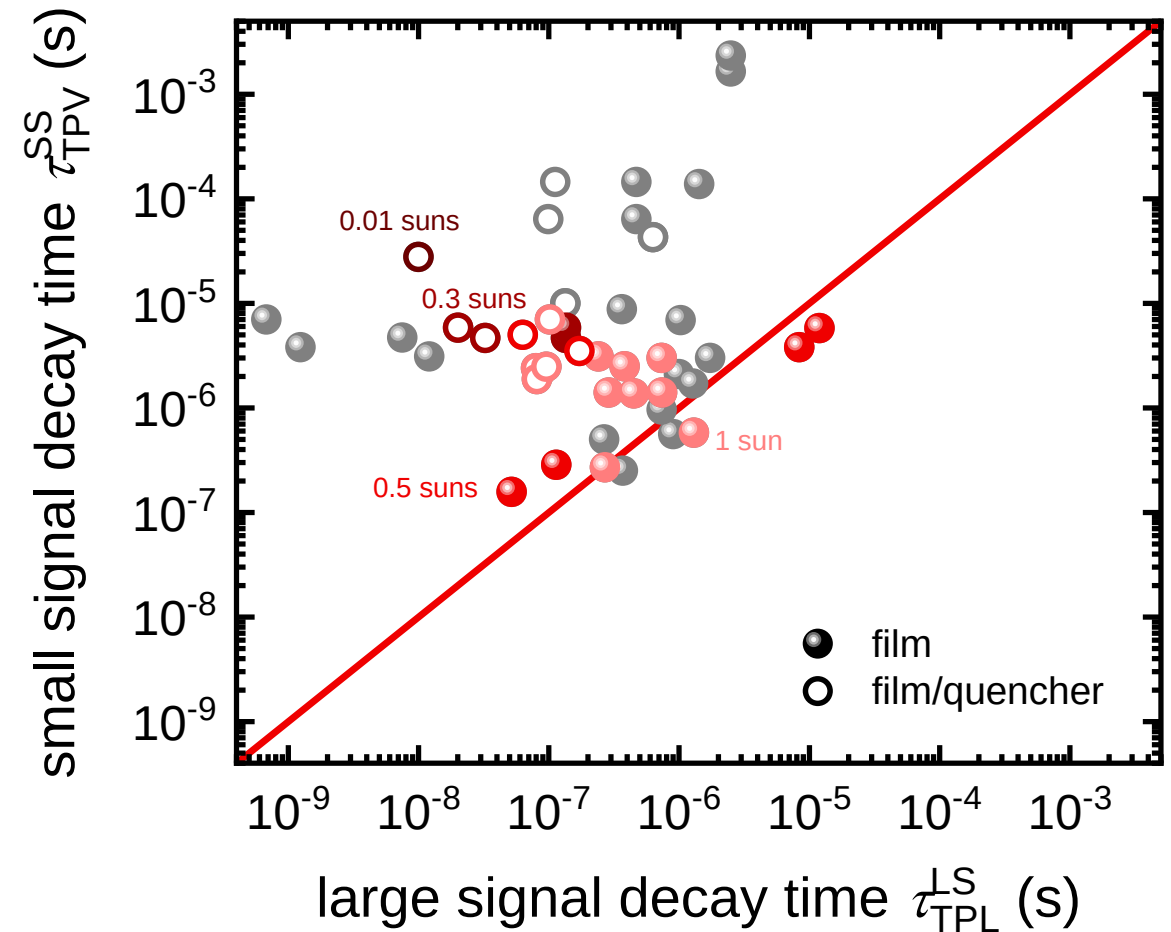
Lifetimes

Observation:

Lifetimes depend on the method and sample type

Problem:

Lifetimes are not actual recombination lifetimes but decay times that are affected also by e.g. capacitive discharge of electrodes.



What could possibly go wrong?

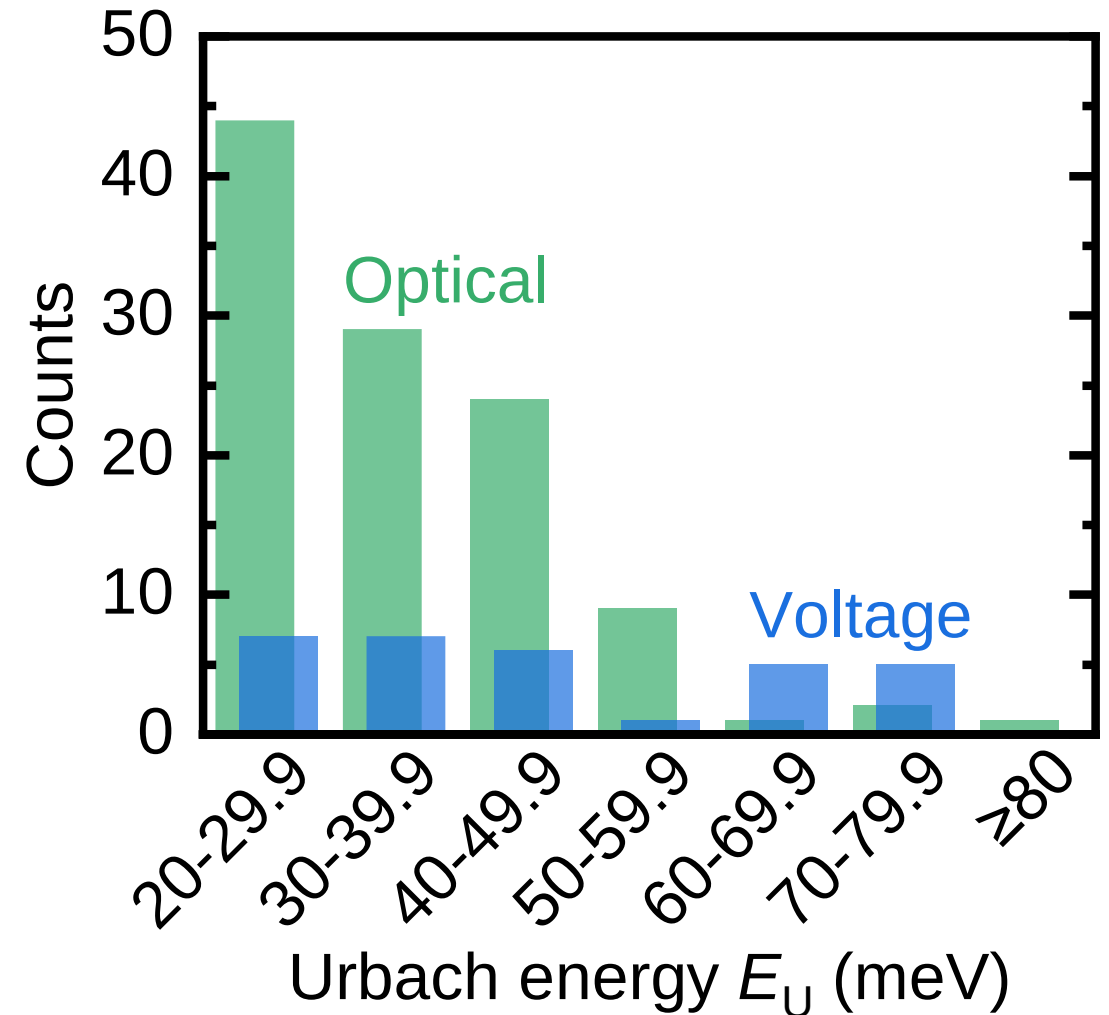
Urbach energies

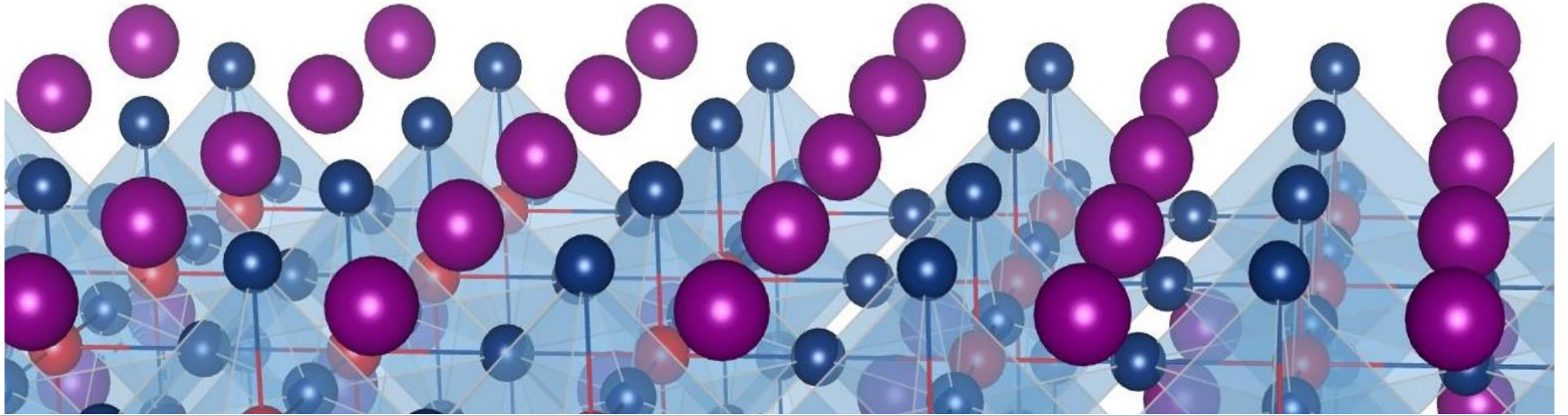
Observation:

Method-dependent Urbach tail

Problem:

Electrical methods are often affected by low mobilities (resistive effects) and show artificially large Urbach tails





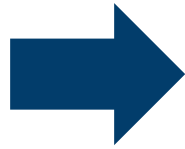
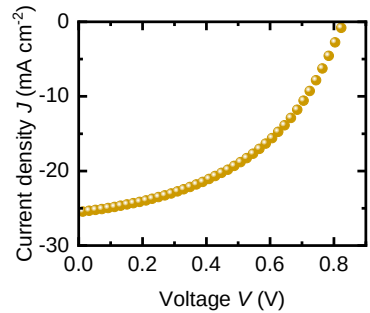
PART 1: INFERENCE OF ELECTRONIC PROPERTIES

THICKNESS AND LIGHT INTENSITY DEPENDENT DATA

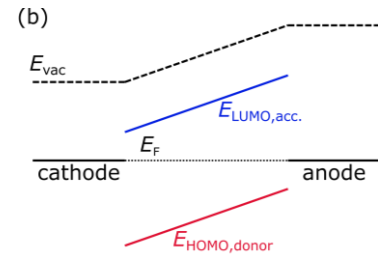
Bayesian Inference

Method

Experimental
Data



Device model

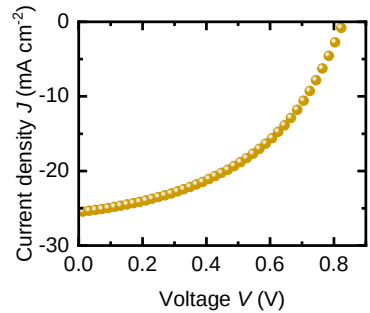


variables: μ , τ , ...
lower boundaries: $1e-9$, $1e-7$, ...
upper boundaries: $1e-6$, $1e-5$, ...

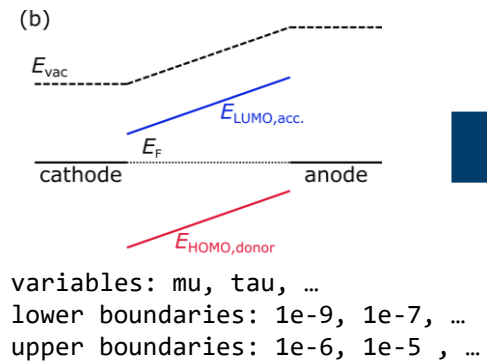
Bayesian Inference

Method

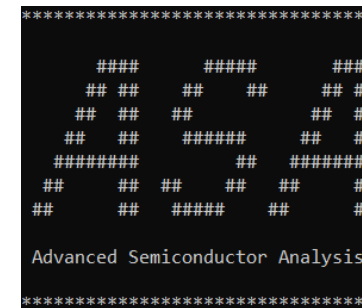
Experimental
Data



Device model

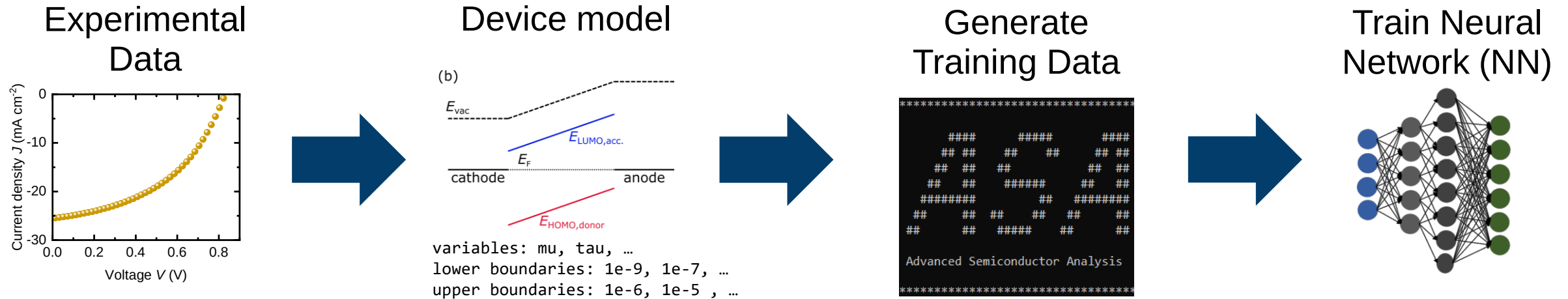


Generate
Training Data



Bayesian Inference

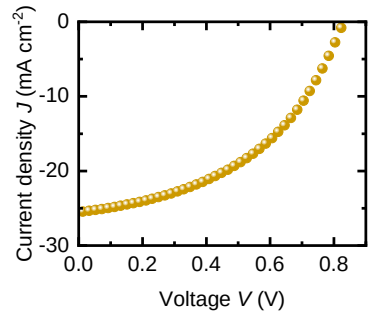
Method



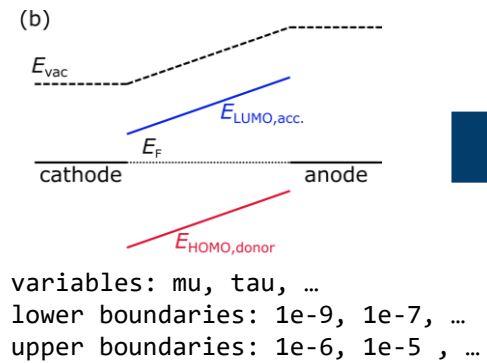
Bayesian Inference

Method

Experimental
Data



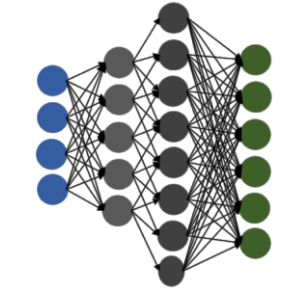
Device model



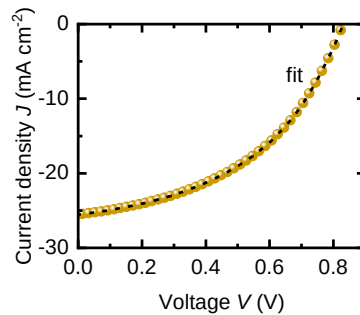
Generate
Training Data

```
*****  
###      #####      ###  
## ##   ##   ##   ##  
## ##   ##   ##   ##  
#####   ##   #####  
##   ##   ##   ##   ##  
#####   ##   #####  
##   ##   ##   ##   ##  
##   ##   ##   ##   ##  
*****  
Advanced Semiconductor Analysis  
*****
```

Train Neural
Network (NN)

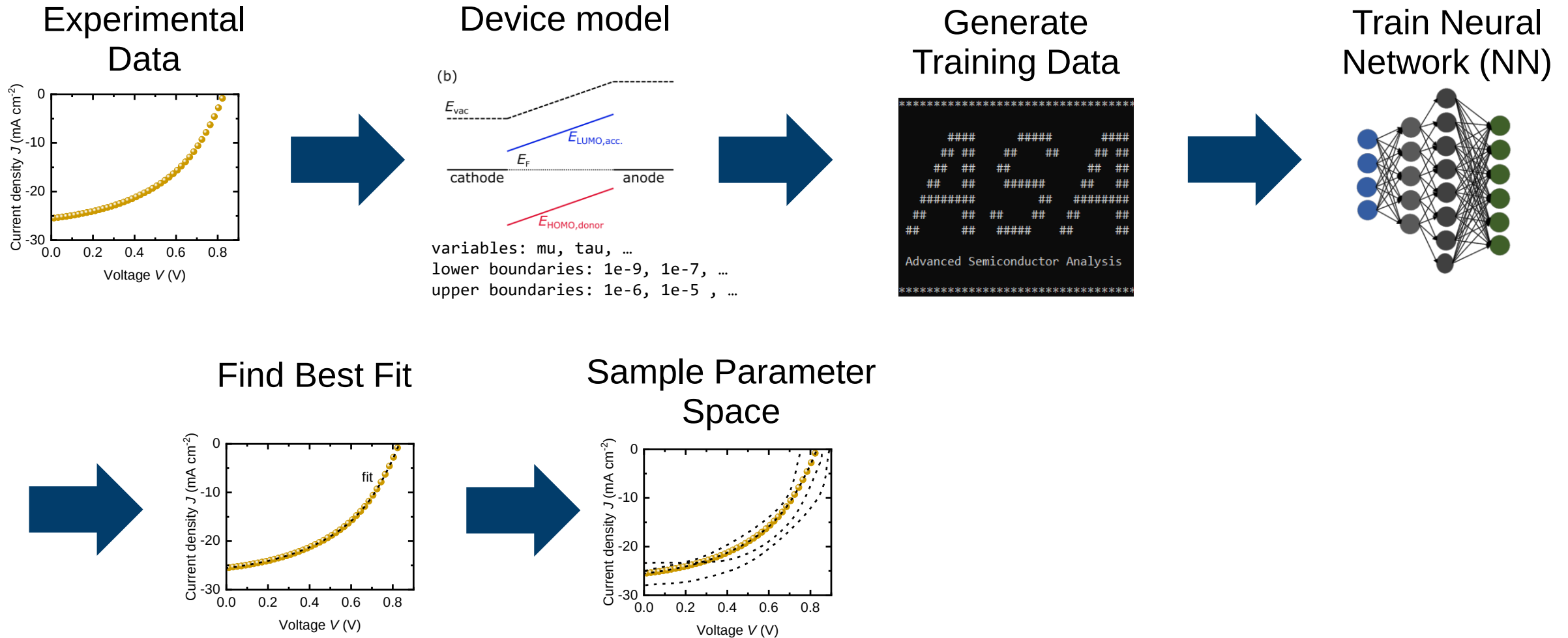


Find Best Fit



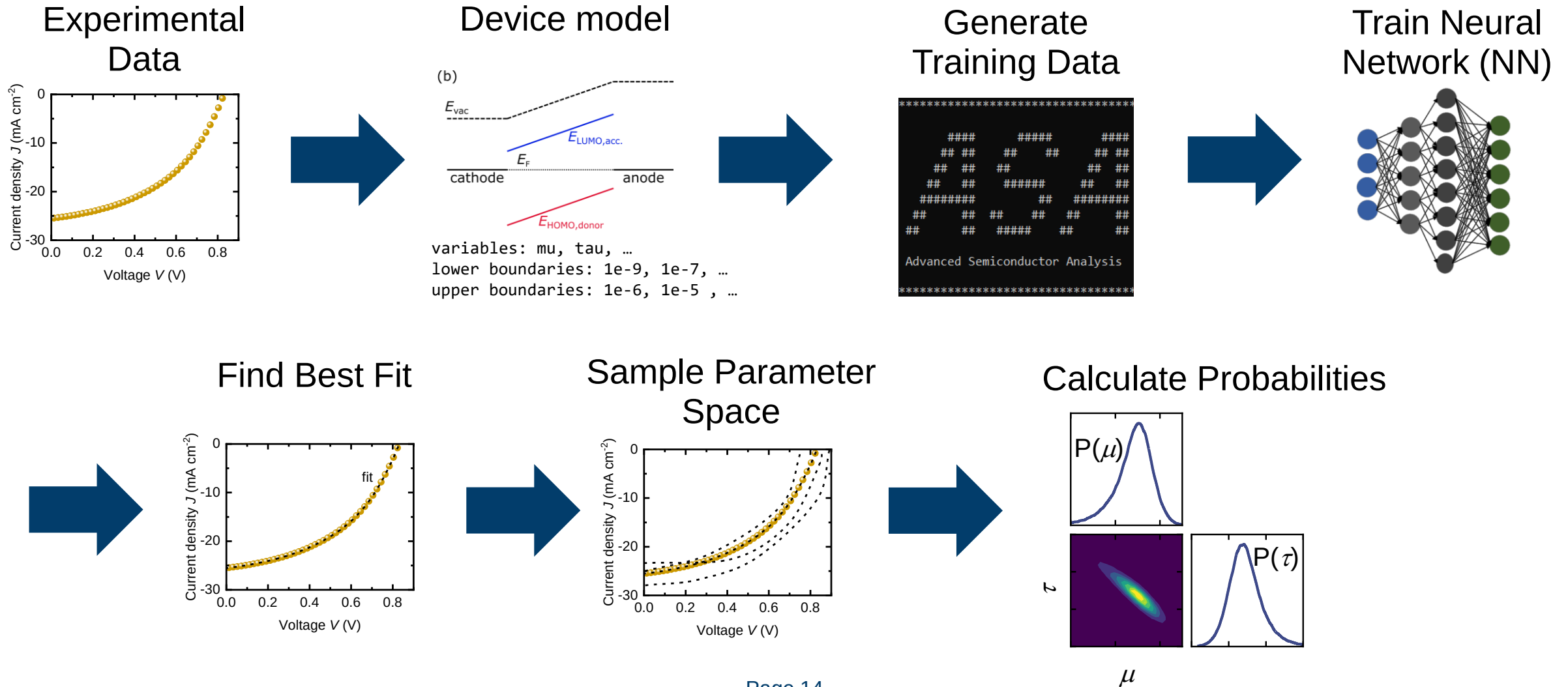
Bayesian Inference

Method



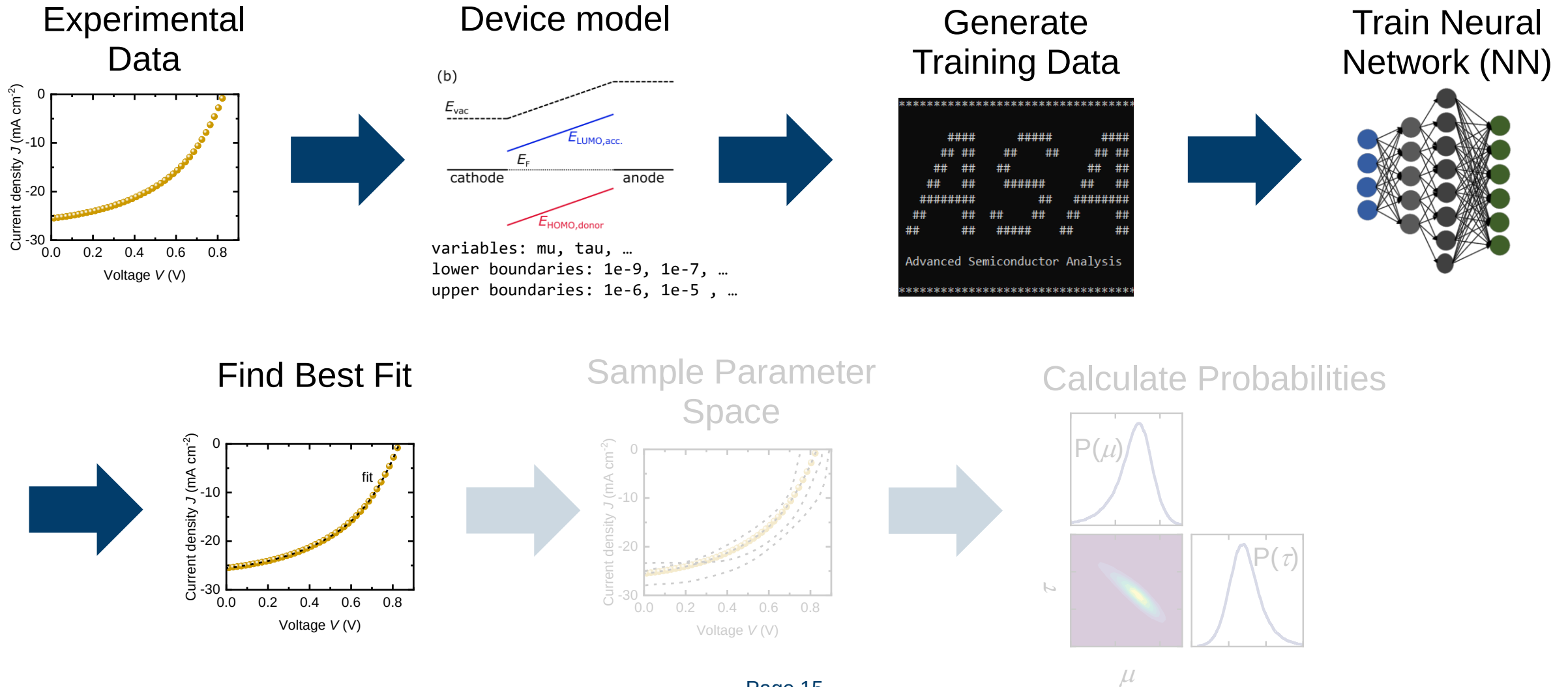
Bayesian Inference

Method

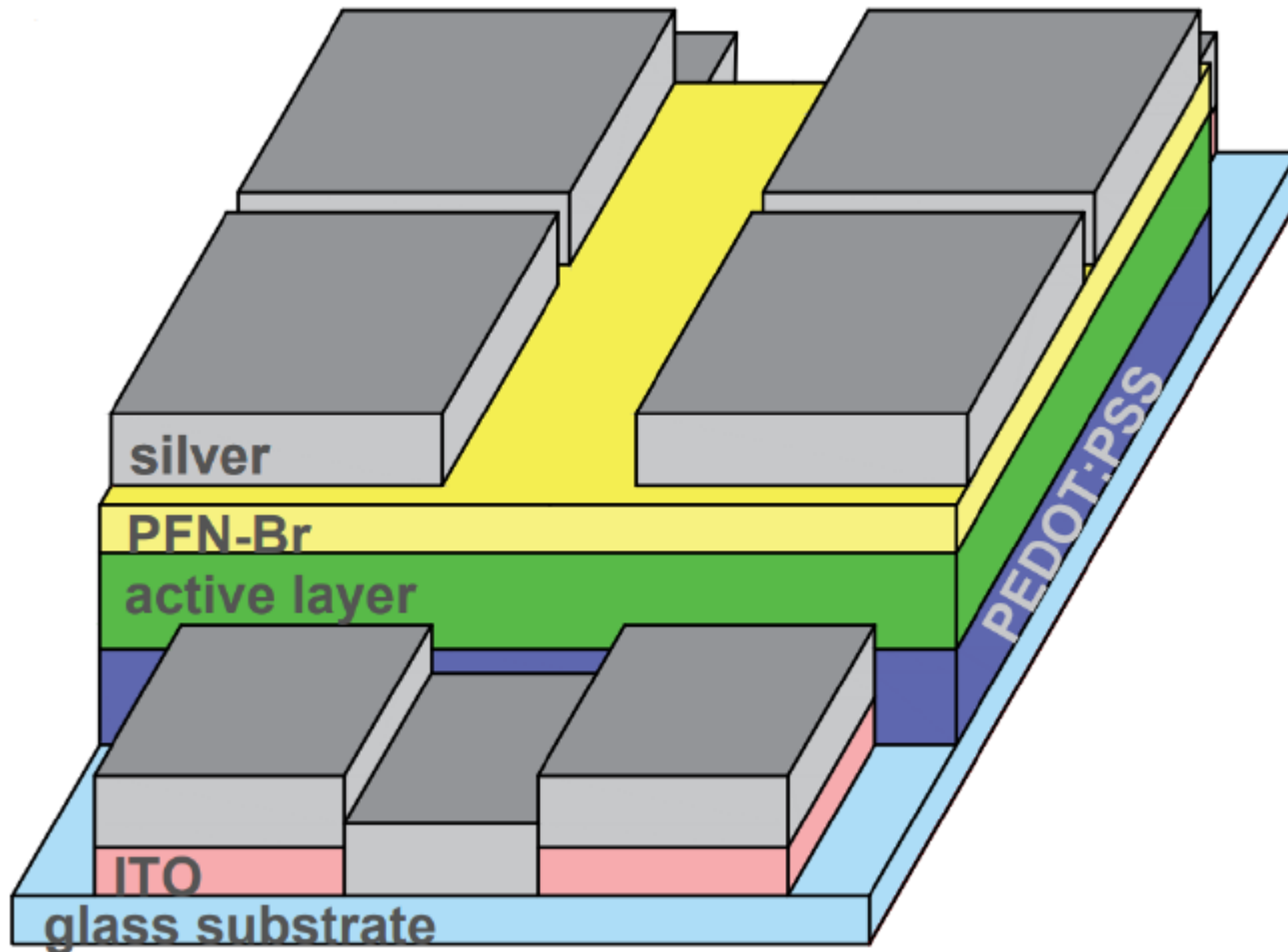


Bayesian Inference

Method

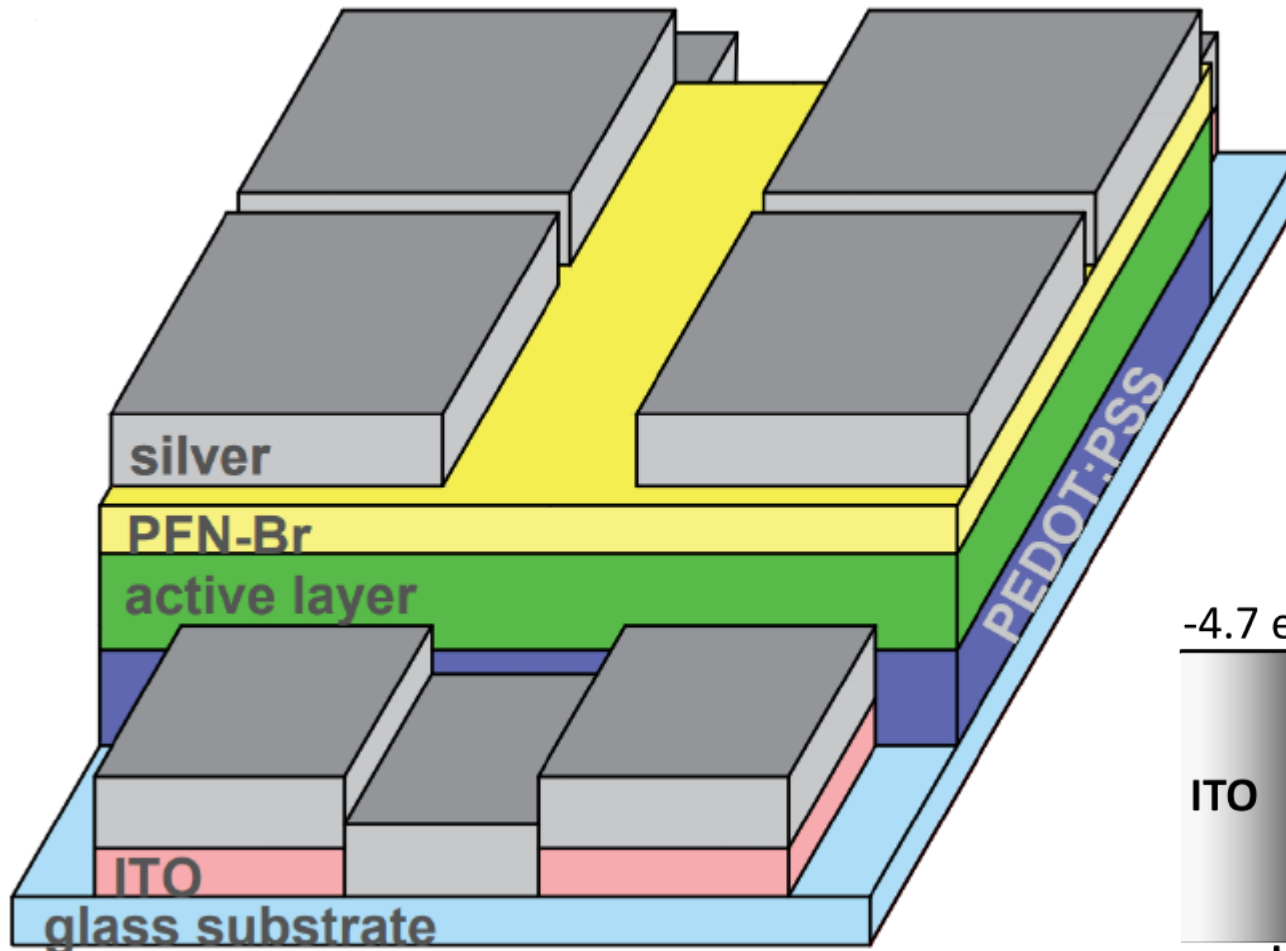


Device Architecture



Experimental Data

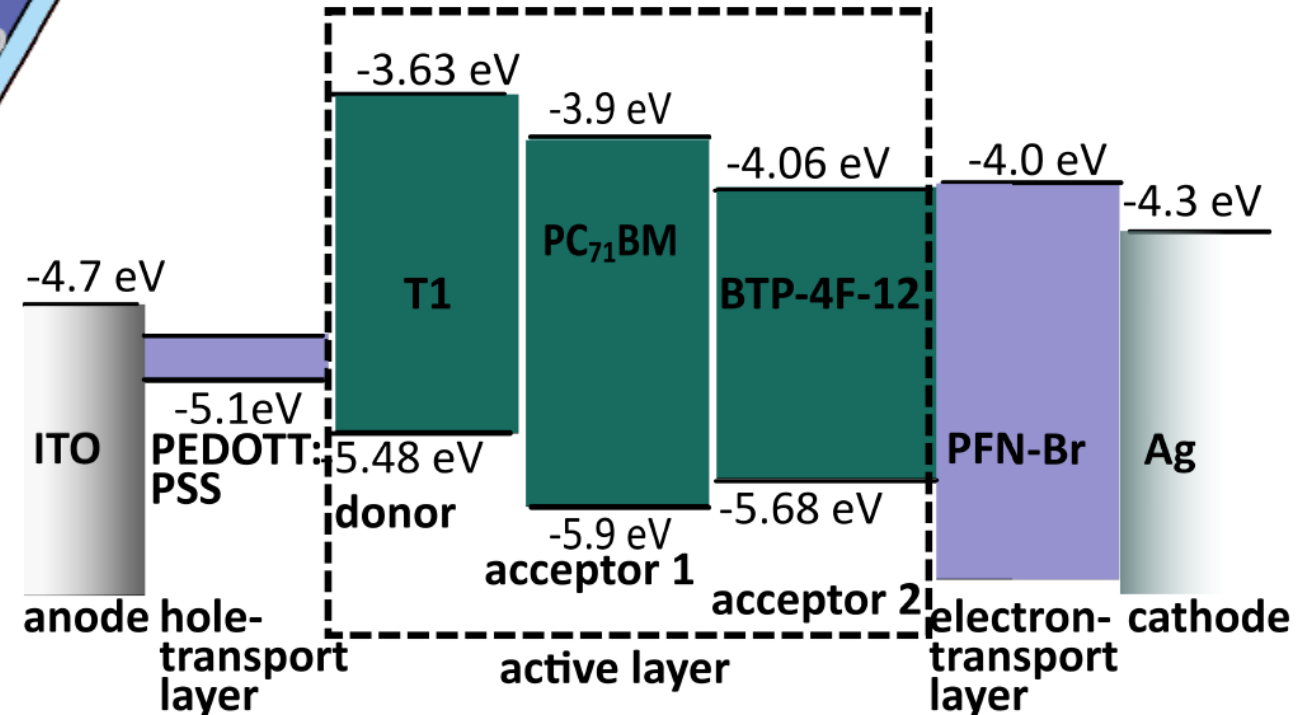
Device Architecture

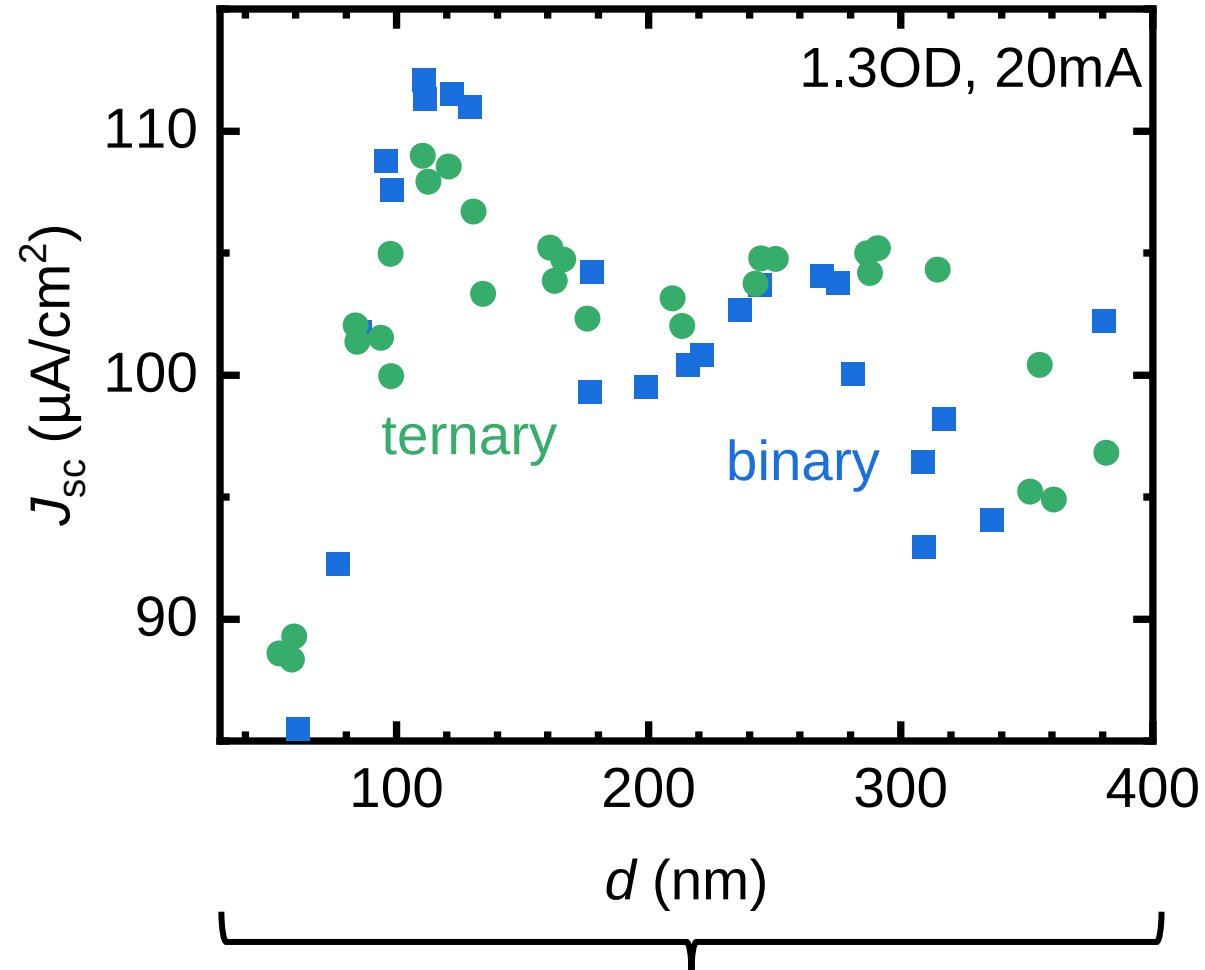


Cell area: 0.16 cm²

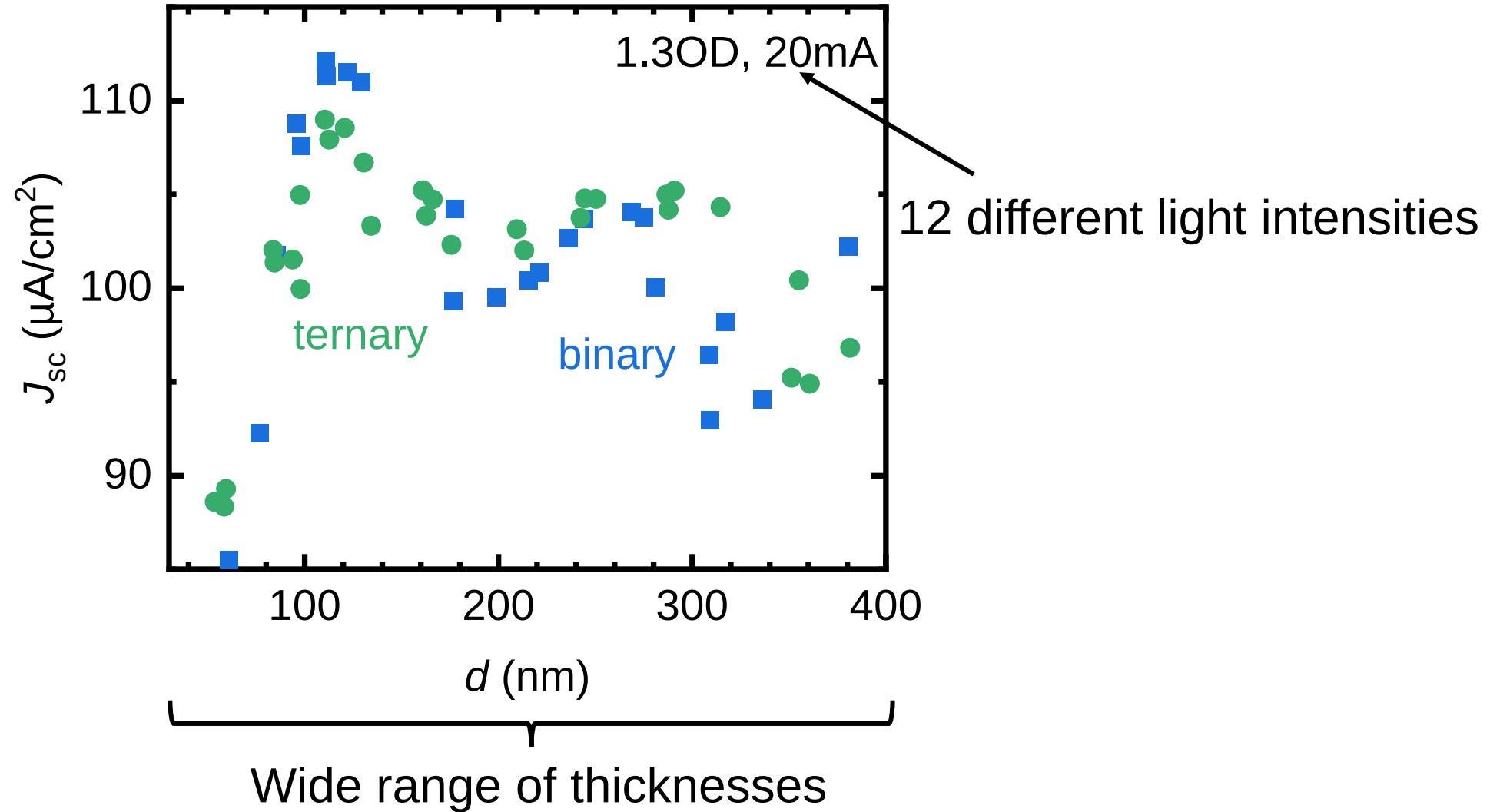
Active layers:

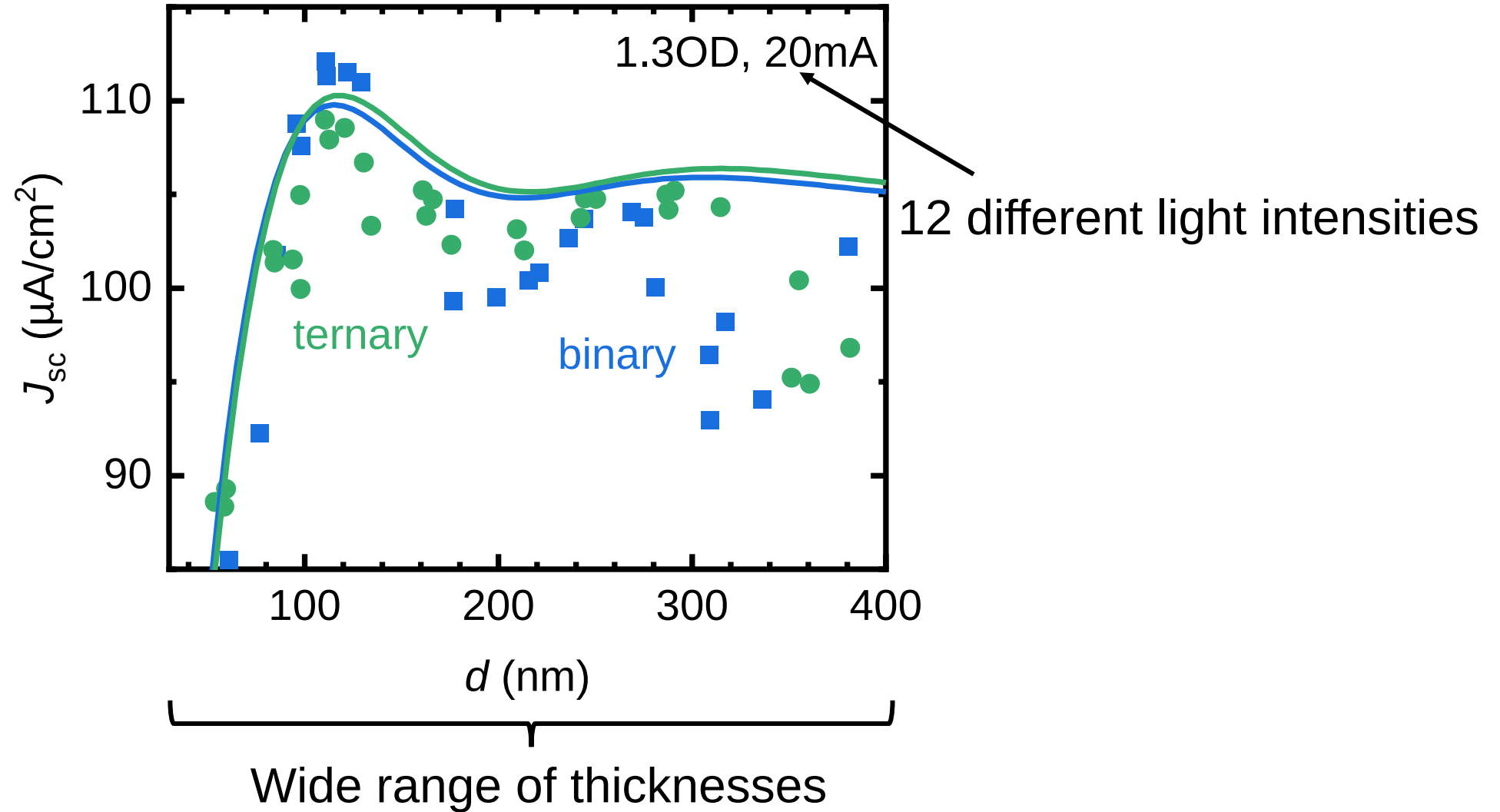
- Binary blend (BTP-4F-12: PBDB-TF-T1)
- Ternary blend (BTP-4F-12: PBDB-TF-T1:PC71BM)





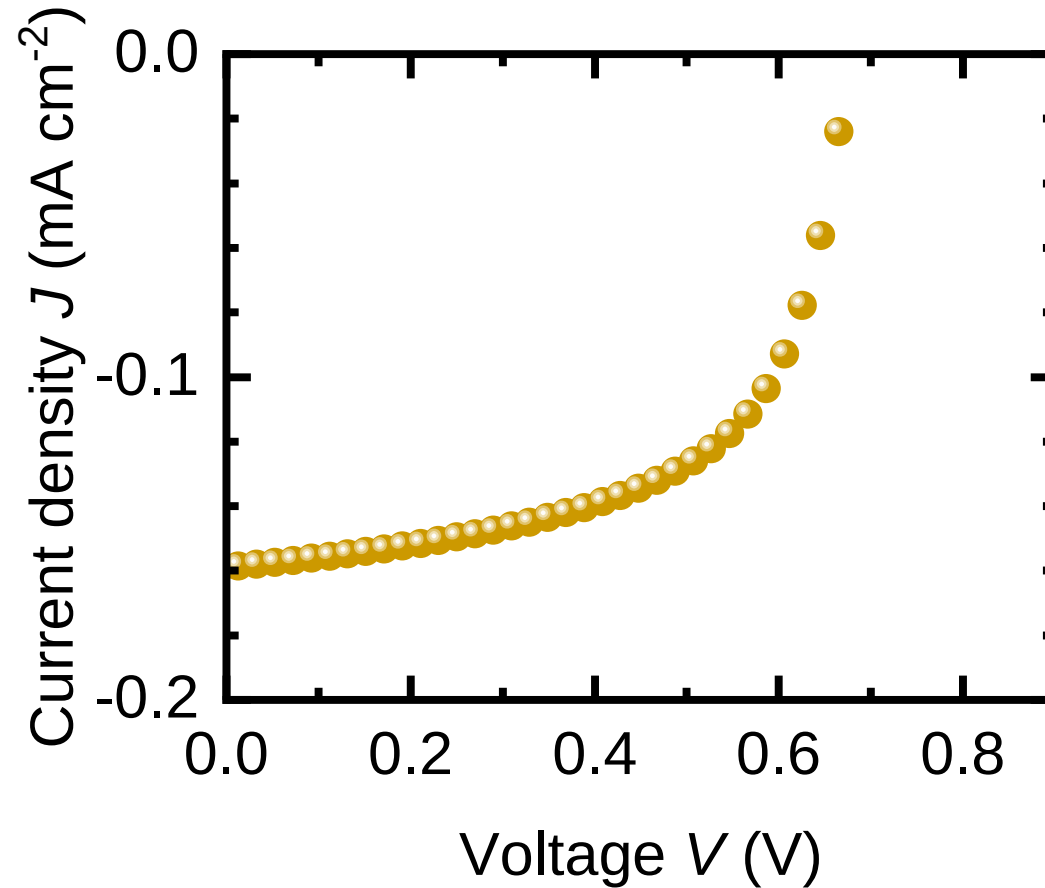
Wide range of thicknesses





Experimental Data

What Do We Fit?

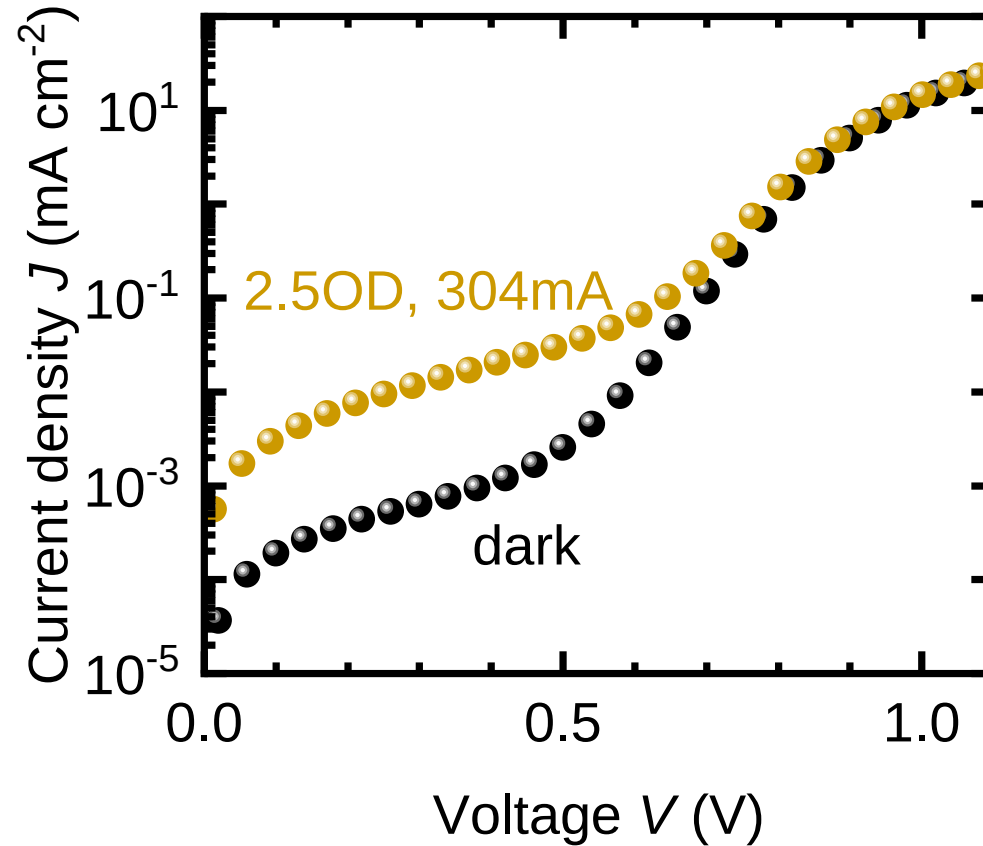


$$\Delta J_{\text{rec}}(V, \Phi) = J_{\text{illu}}(V, \Phi) - J_{\text{sc}}(\Phi)$$

Experimental Data

What Do We Fit?

- Independence of inaccuracies in optical model

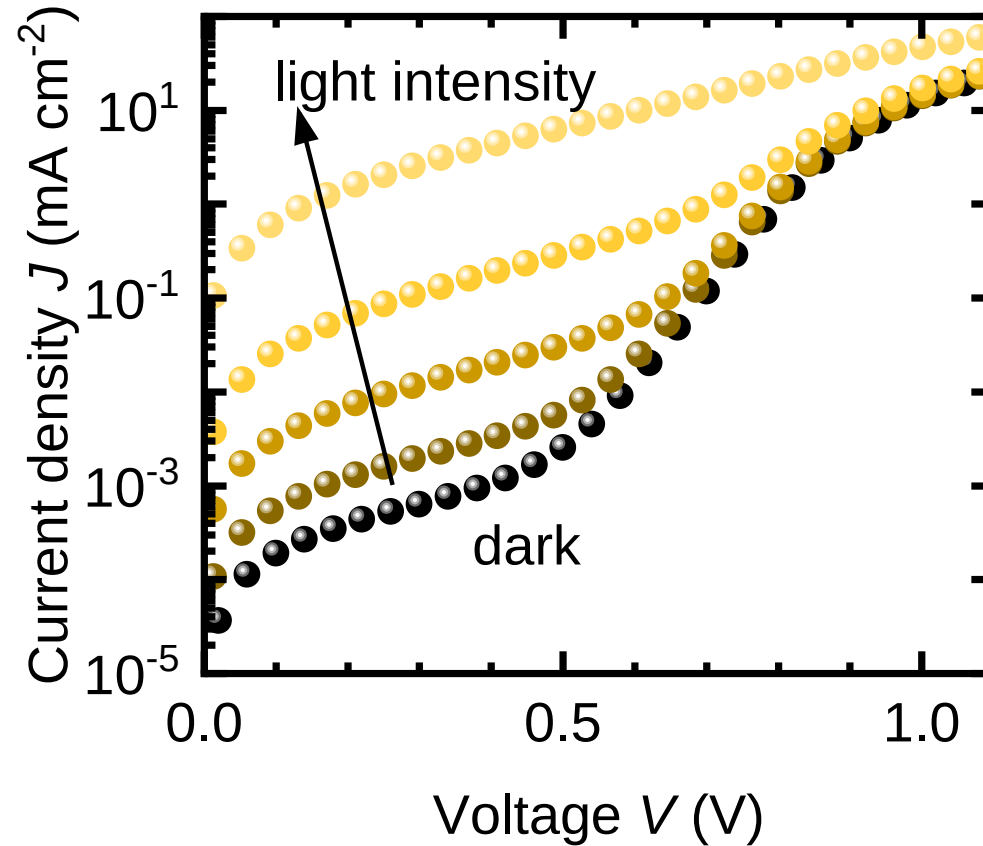


$$\Delta J_{\text{rec}}(V, \Phi) = J_{\text{illu}}(V, \Phi) - J_{\text{sc}}(\Phi)$$

Experimental Data

What Do We Fit?

- Independence of inaccuracies in optical model
- Emphasis on light-intensity dependent recombination current density

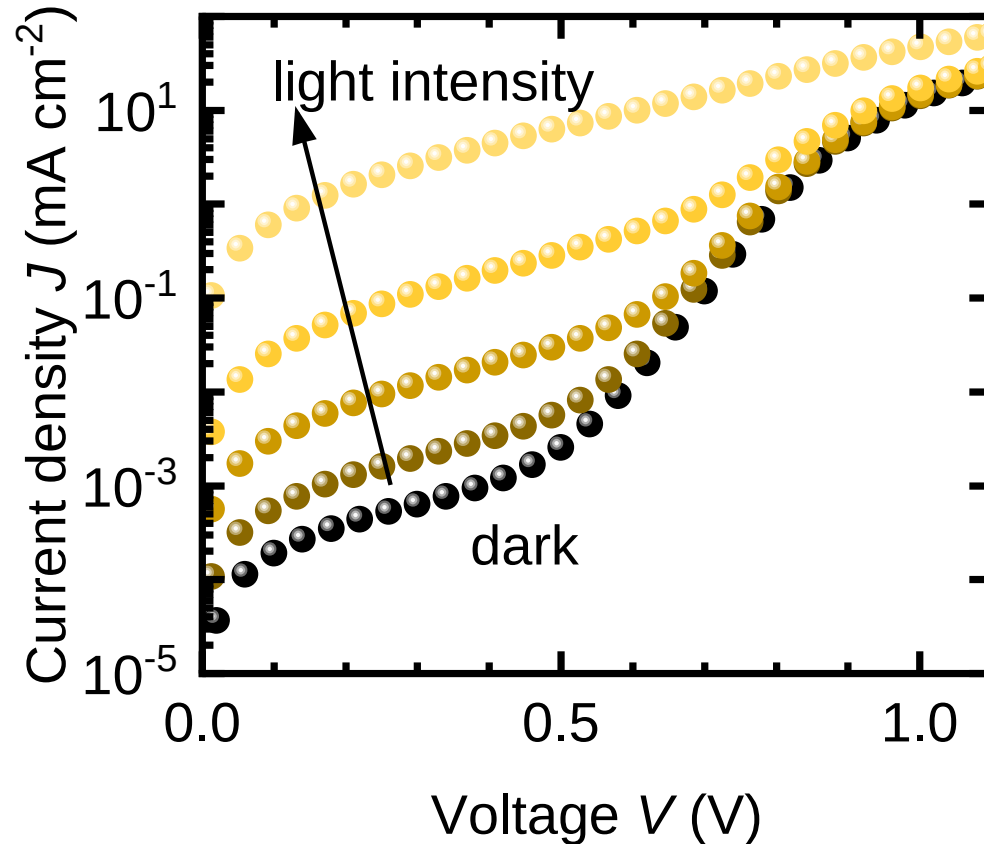


$$\Delta J_{\text{rec}}(V, \Phi) = J_{\text{illu}}(V, \Phi) - J_{\text{sc}}(\Phi)$$

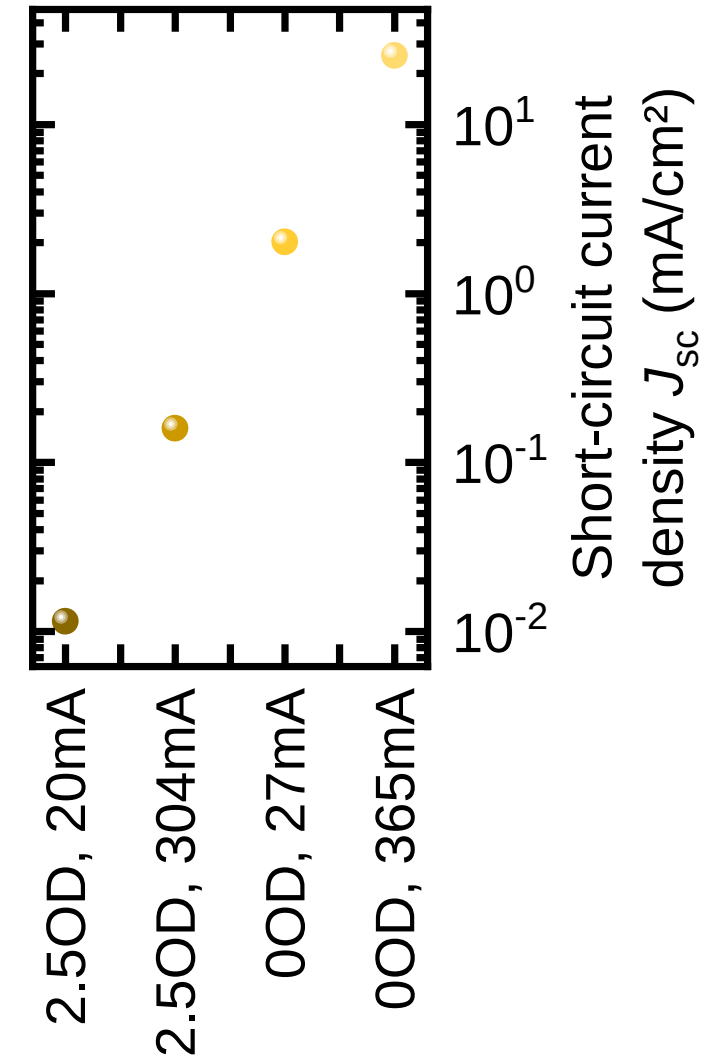
Experimental Data

What Do We Fit?

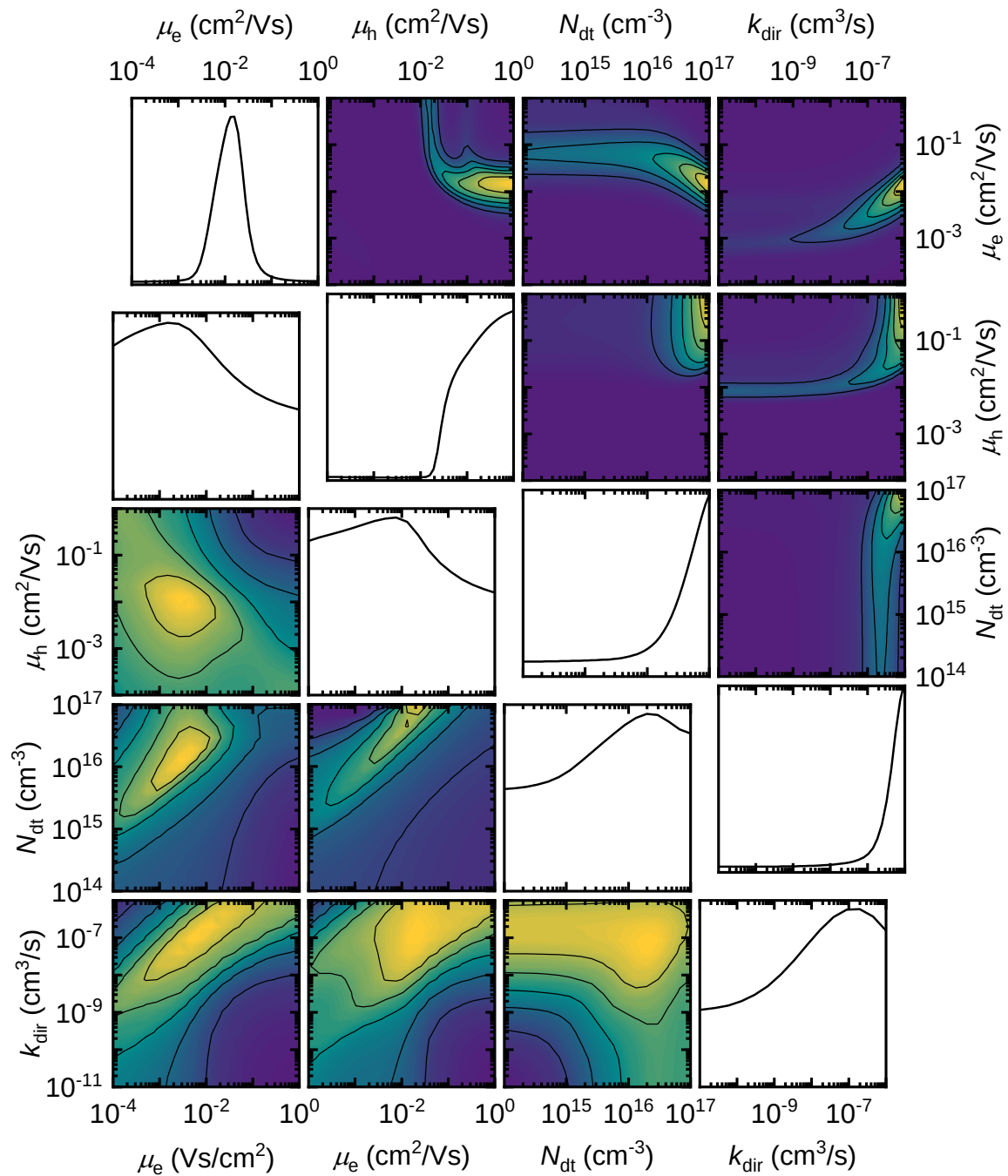
- Independence of inaccuracies in optical model
- Emphasis on light-intensity dependent recombination current density
- Use J_{sc} in fitting procedure to penalize fits that are too far off



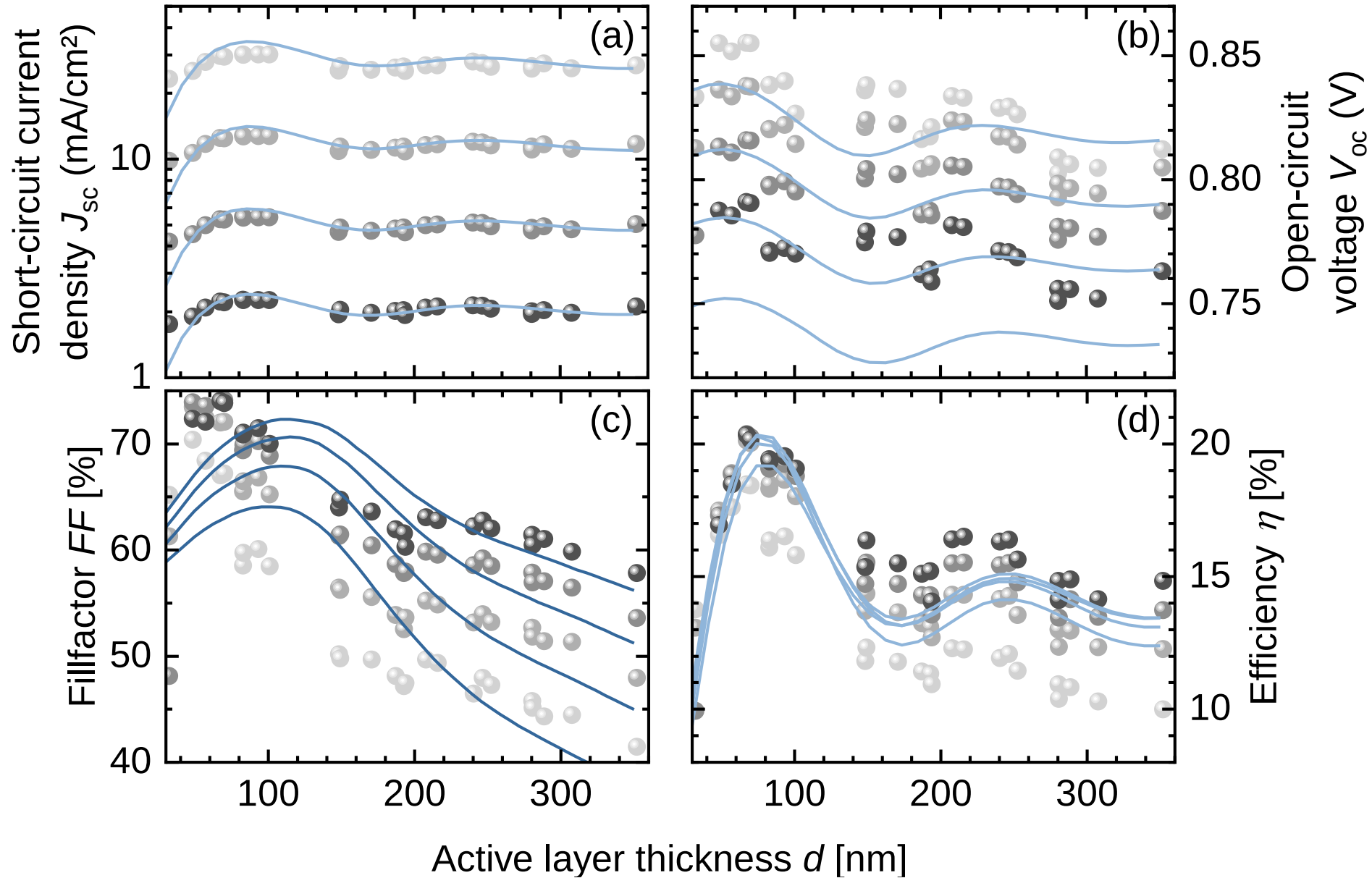
$$\Delta J_{\text{rec}}(V, \Phi) = J_{\text{illu}}(V, \Phi) - J_{\text{sc}}(\Phi)$$

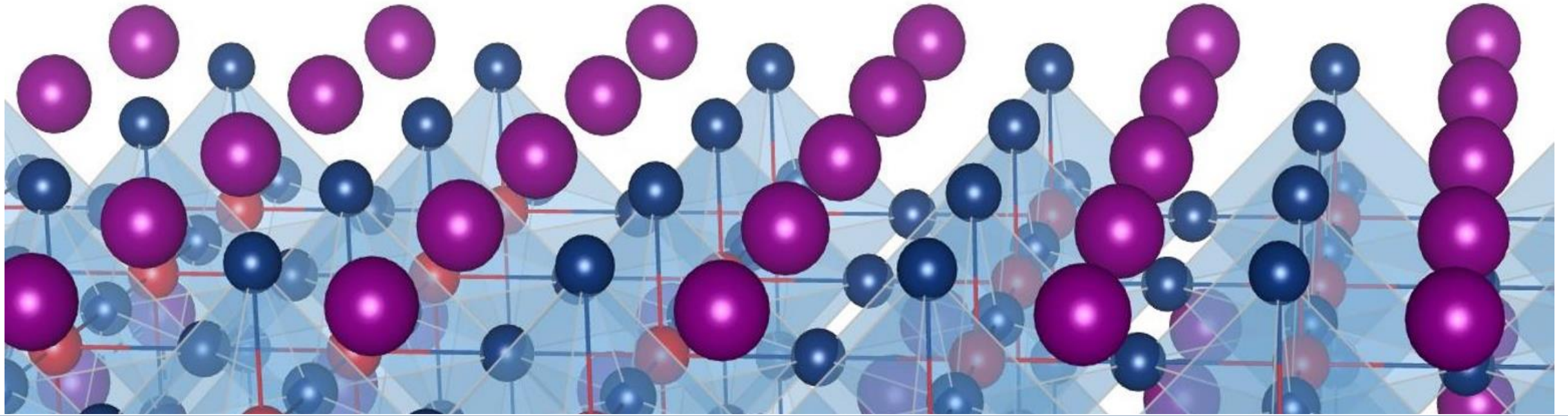


Cornerplots



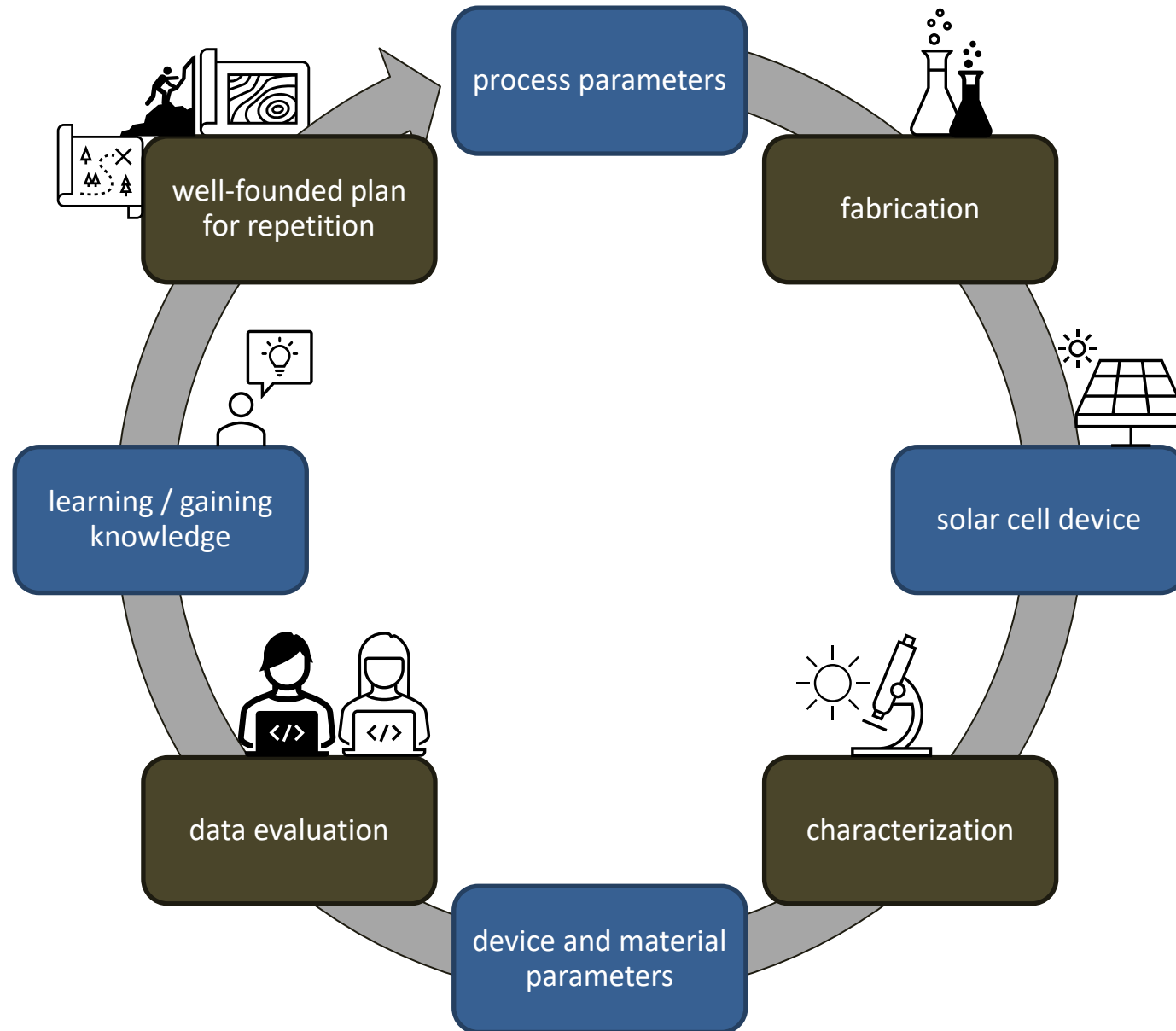
Trends with Thickness



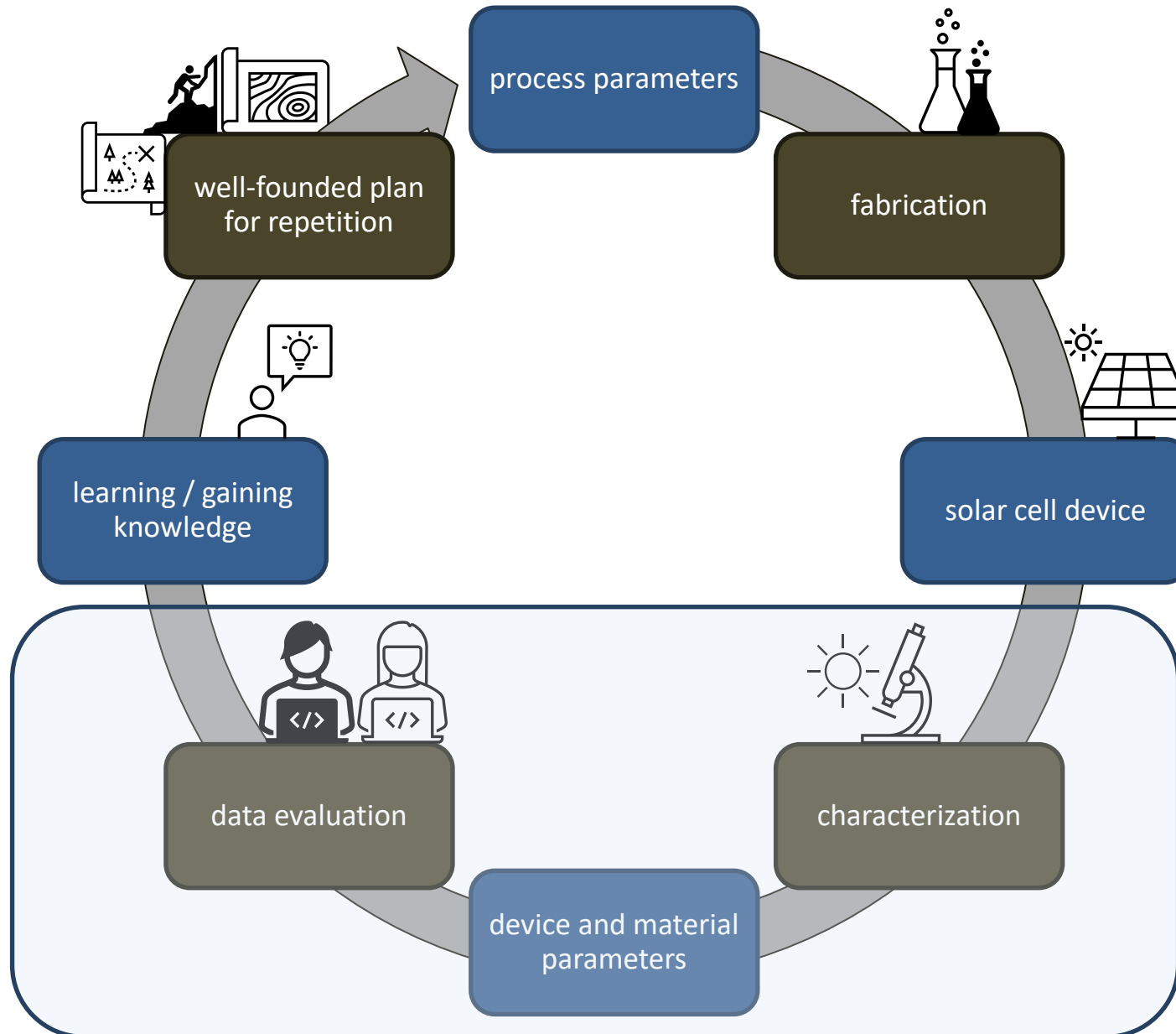


PART 2: THE VALUE OF DEVICE CHARACTERIZATION FOR THE PURPOSE OF DEVICE OPTIMIZATION

How we imagine scientific progress in the field

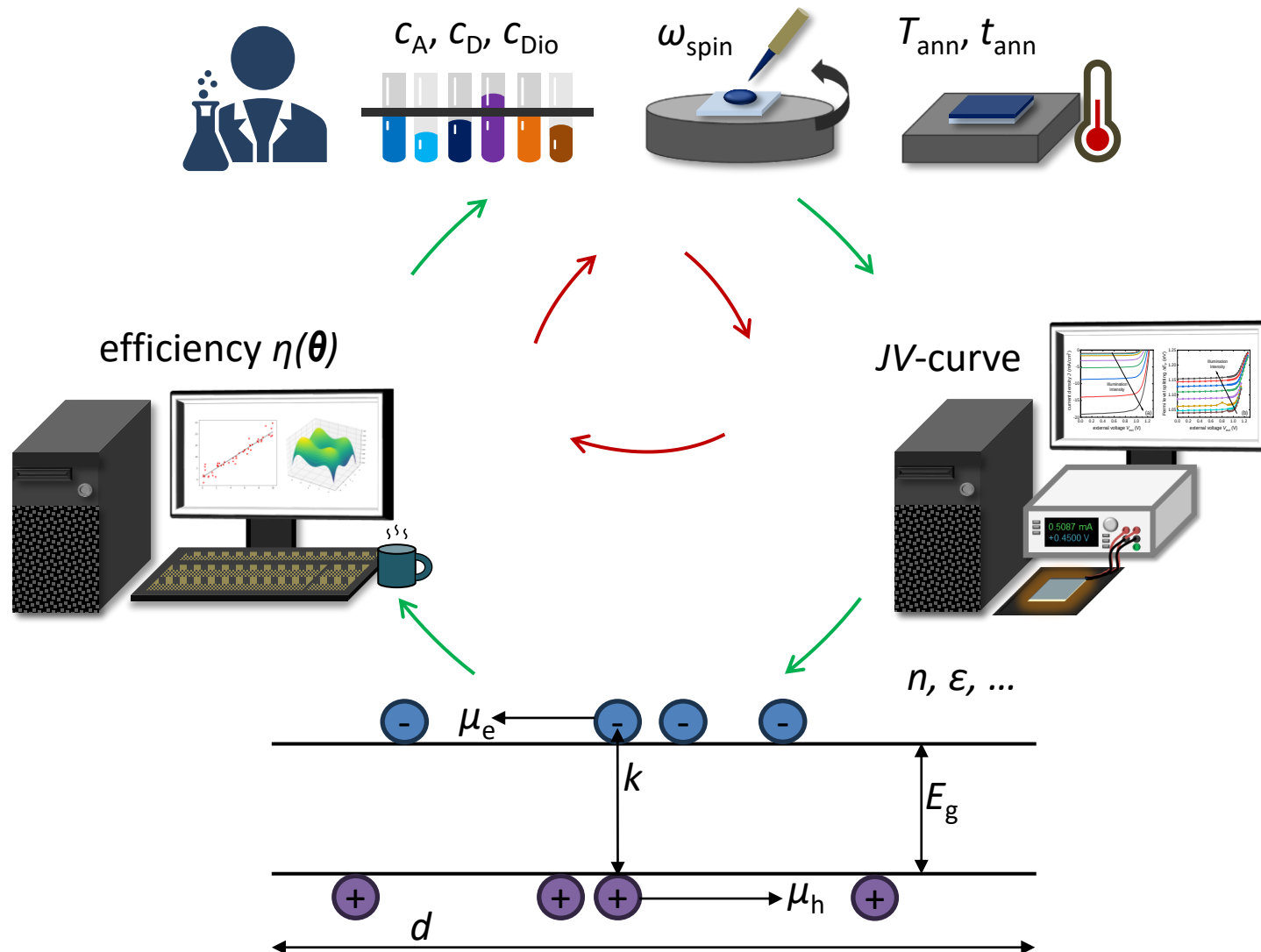


How we imagine scientific progress in the field



Is this important for papers and our understanding or for device optimization itself?

Idea: Test 2 Options in Virtual Laboratory



Option 1:

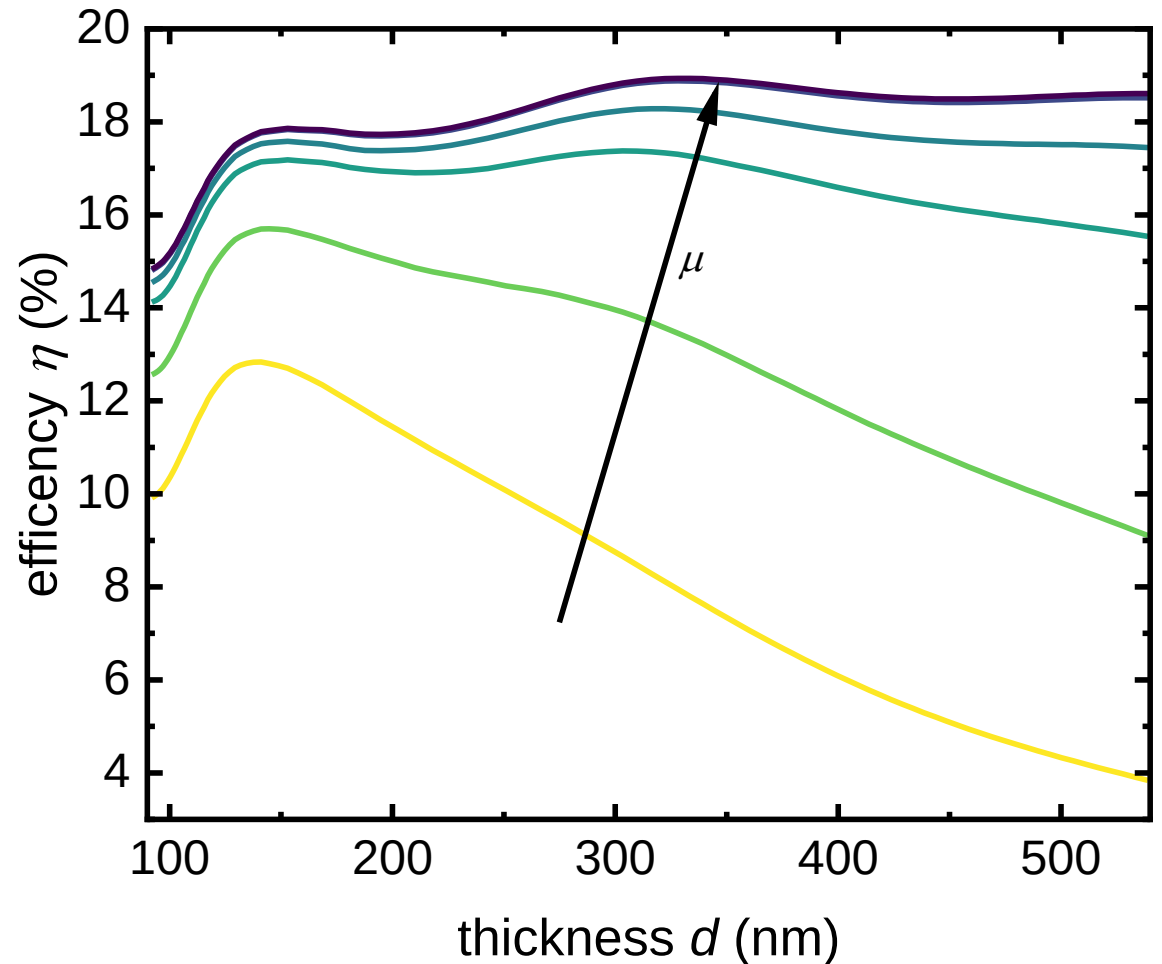
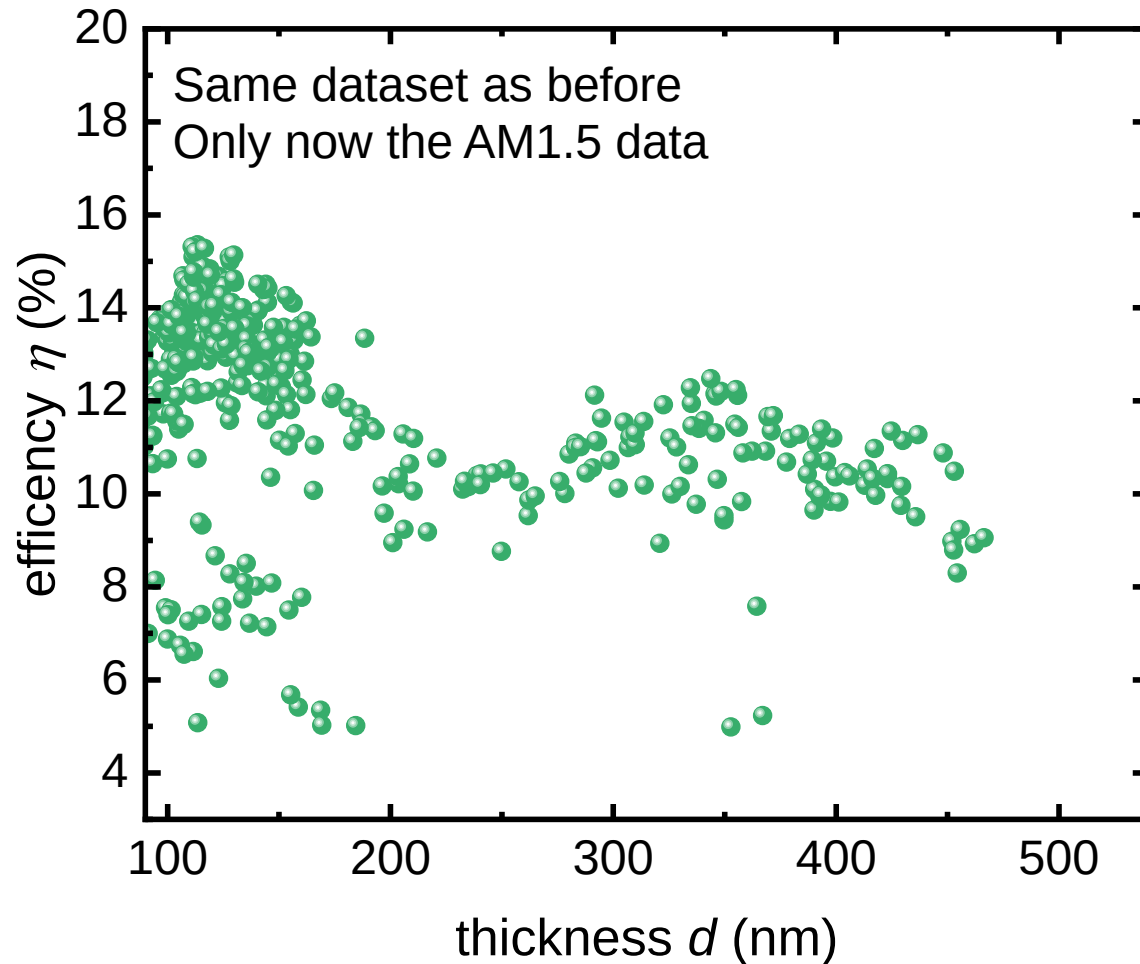
- Process parameters $\rightarrow$ JV curve
- JV curve $\rightarrow$ efficiency
- Efficiency $\rightarrow$ new process parameters

Option 2:

- Process parameters $\rightarrow$ JV curve
- JV curve $\rightarrow$ mobility, recombination coefficient, etc...
- Mobility, rec... $\rightarrow$ efficiency
- Efficiency $\rightarrow$ new process parameters

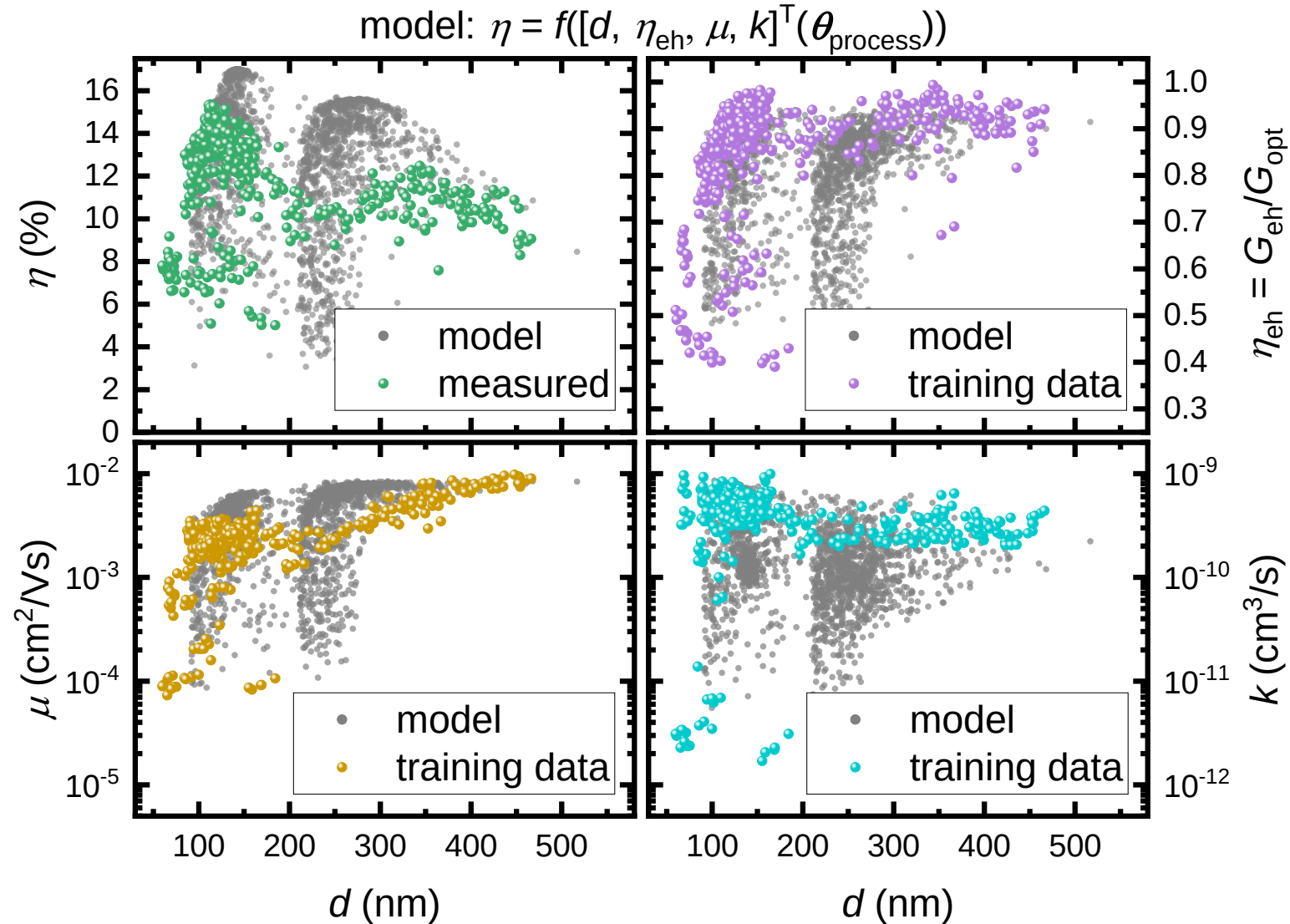
Experimental Basis

To feed the virtual laboratory

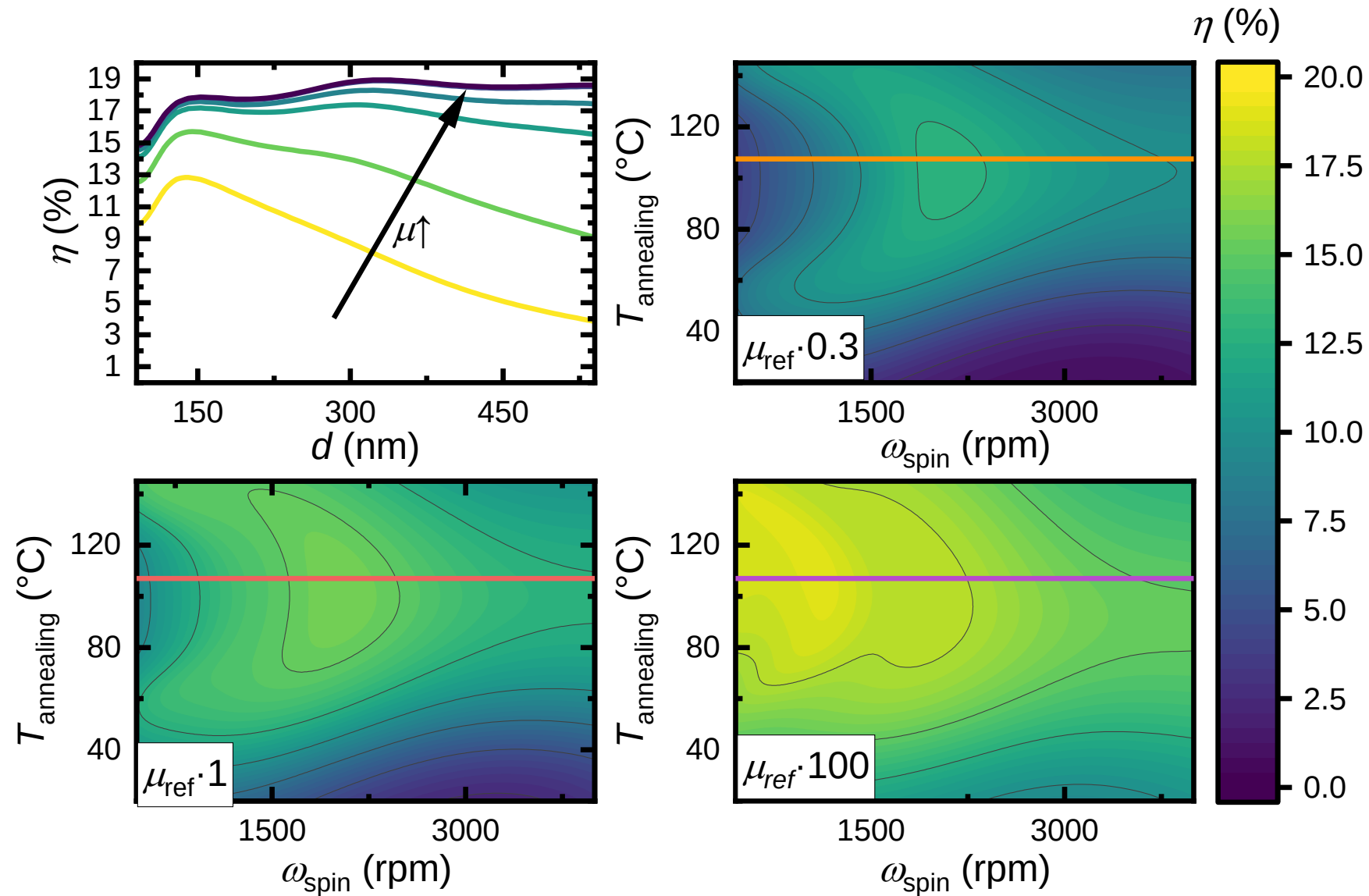


Linking Process with Material Parameters

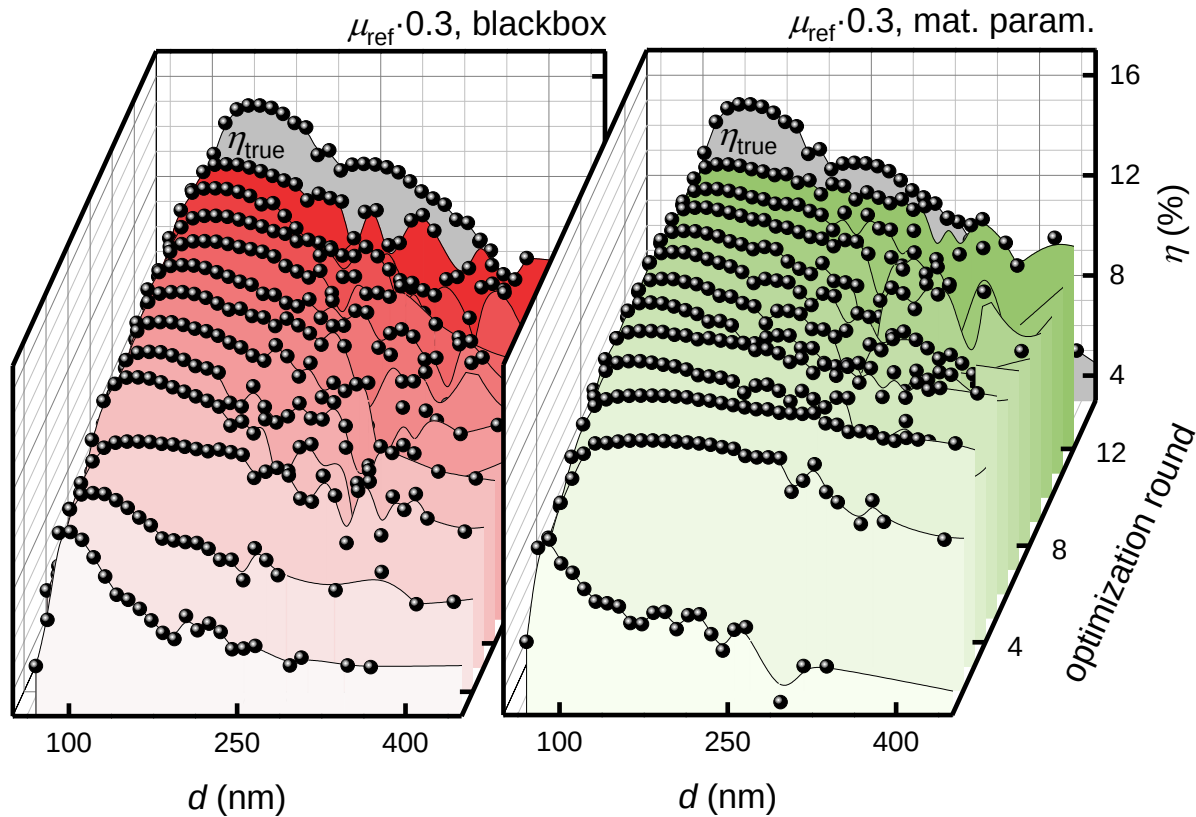
1. Fit simple model to experimental JV data
2. Infer material parameters
3. Plot them vs. process parameters
4. Create a multidimensional function approximation for material vs. process parameters using a SVR
5. Use this as the „truth“ for the virtual laboratory



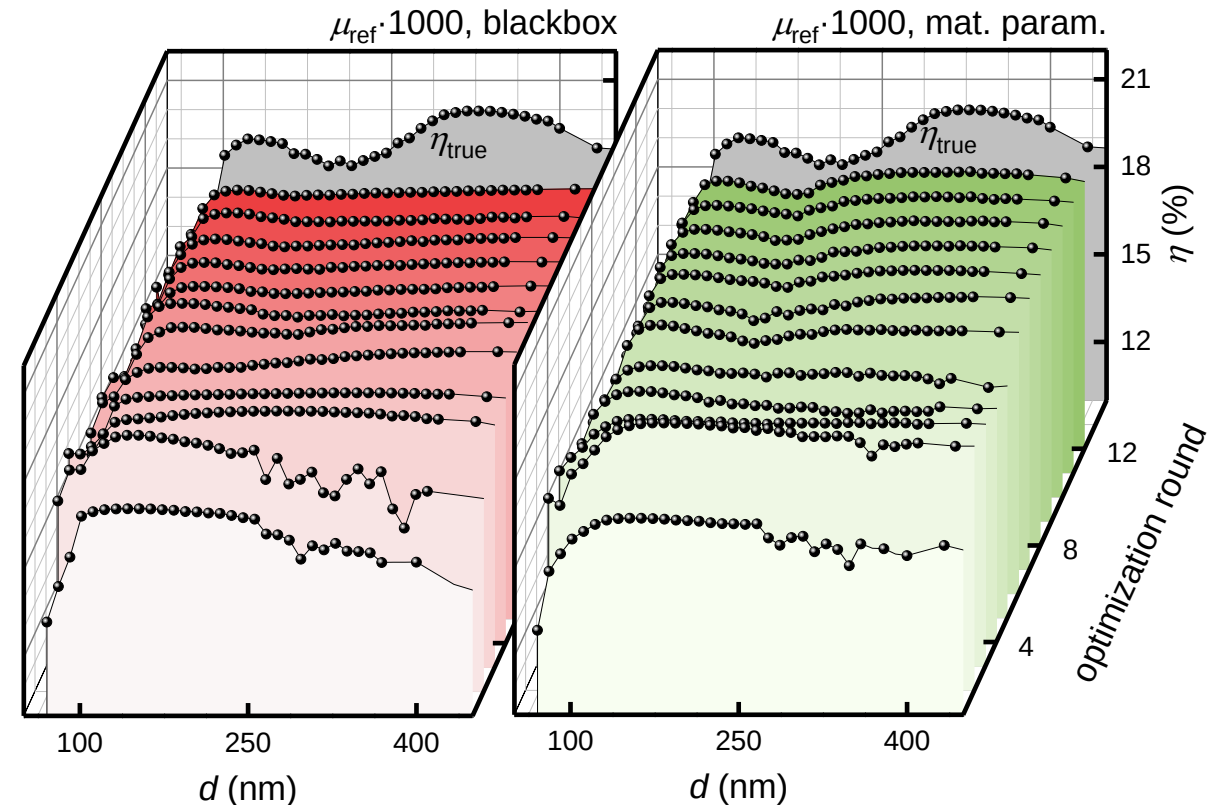
Example slices through the SVR model



Comparison blackbox optimization Vs. material-parameter-based optimization

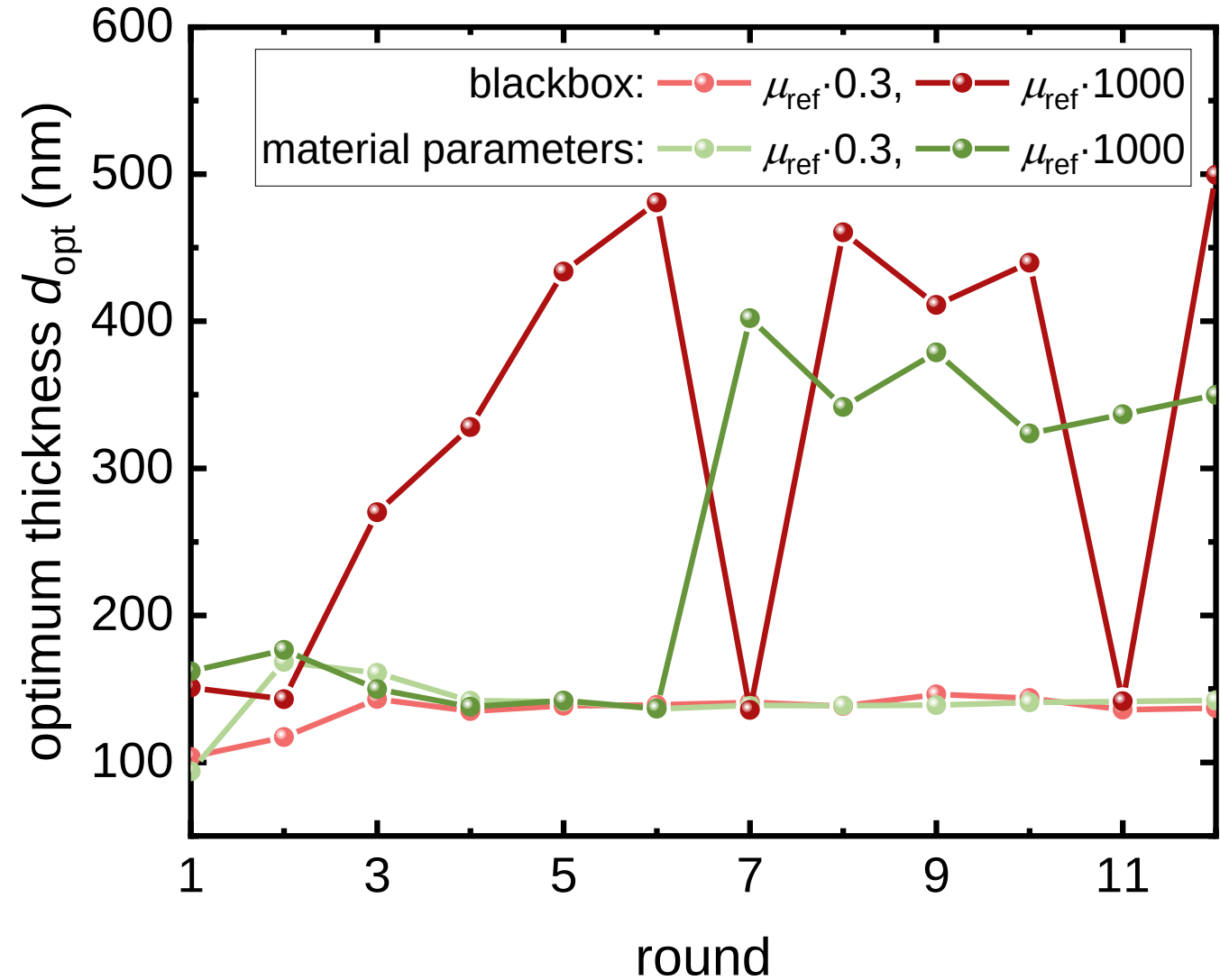
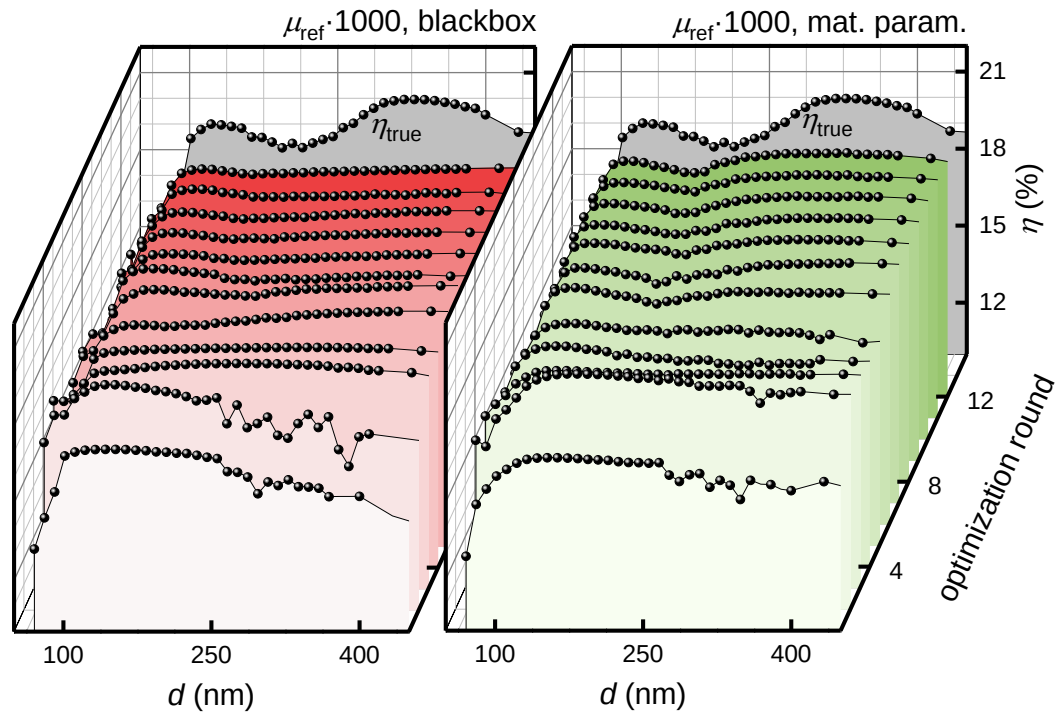


Low mobility



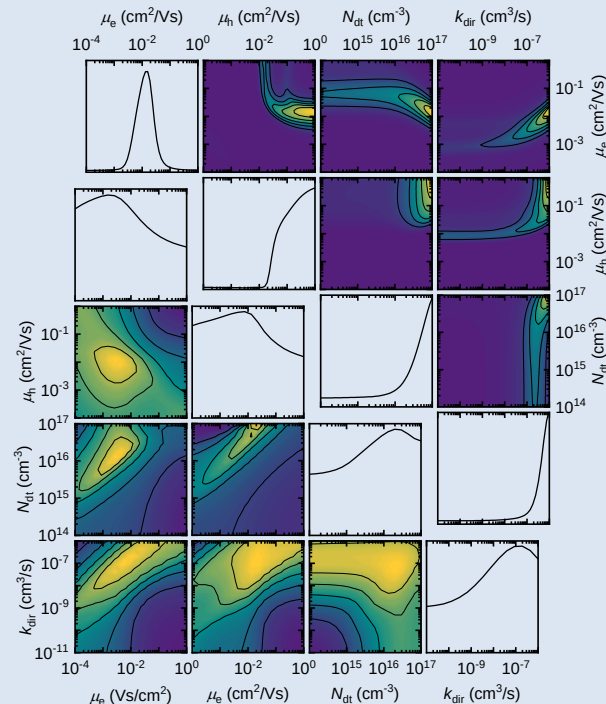
High mobility

Does the optimization find the 2nd interference maximum?



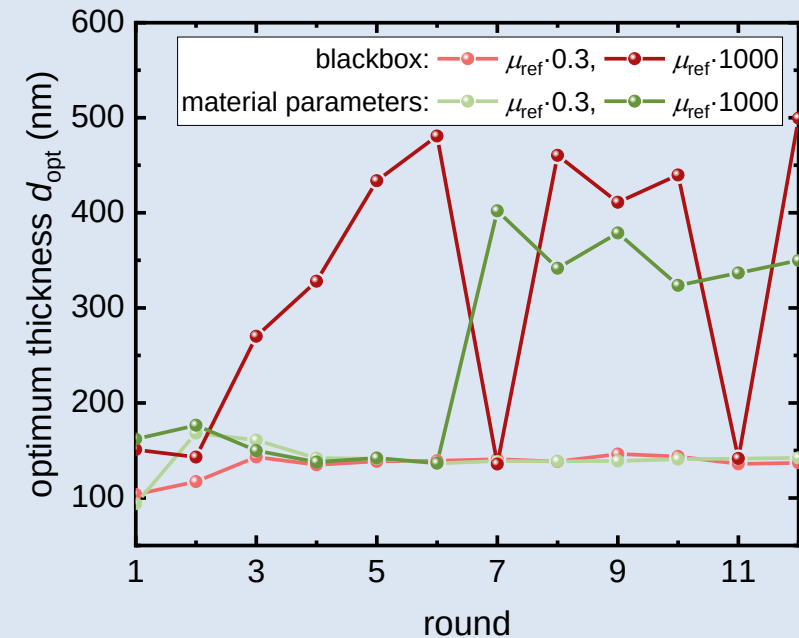
1) Inferring Parameters

- NNs interpolate well and look up well
- Trained NNs can therefore accelerate simulations by a factor $\sim 10^4$ for JV curves
- Allows finding likely material parameters



2) Inferring Parameters

- Models+Characterization might help to find optima in complex η (process parameter) situations.





Funding from
Helmholtz Association
State NRW (progres.nrw)

Thank you for your attention